ADDENDUM NUMBER 1 TO MAINTENANCE MANUAL LBI-38764G

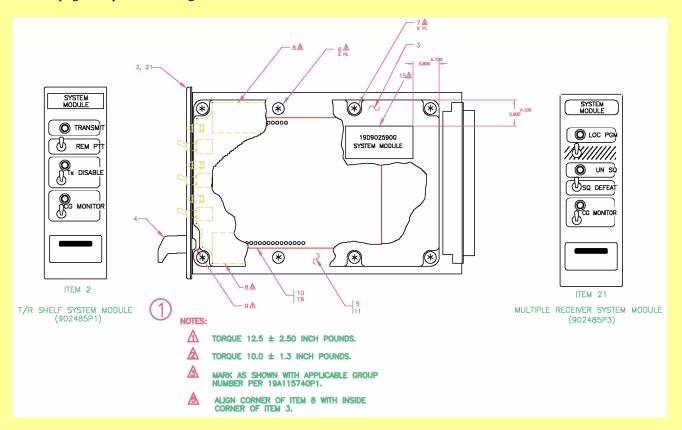
Refer to ECO#20043005

GENERAL

This addendum documents a change to the System Module (19D902590G1, G3, & G5) Maintenance Manual. Torque specification changed from 20 in-lbs. to 12.5 ± 2.50 in-lbs.

CHANGES

On page 6, update drawing 19D902590 with revision 6.



(19D902590, Rev. 6)







SYSTEM MODULE 19D902590G1, G3, G5

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DESCRIPTION

System Module 19D902590 contains all audio processing and control circuitry for the T/R and M/R shelves. The audio processing and routing is done using analog circuitry. The control circuitry utilizes high speed digital components and includes a microprocessor. Due to the high speed digital circuitry, the System Module is housed in an RFI and EMI shield.

There are three types of System Modules for various applications:

- 1. System Module 19D902590G1 incorporates System Board 19D903771G1 and is used in MASTR IIe DC remote applications only.
- System Module 19D902590G3 incorporates System Board 19D903771G1 "piggy backed" with Digital Signal Processing (DSP) Board 19D902667G1. This module is used in all MASTR IIe and MASTR III base station applications, including Enhanced Digital Access Communications System (EDACS).
- System Module 19D902590G5 is identical to System Module 19D902590G3 except for the chassis screen printing. This module is used in MASTR III Auxiliary Receiver applications.

Supply voltages for the System Module are generated by the Power Module and are applied to the System Module through the 96-Pin DIN connector on the backplane board.

CIRCUIT ANALYSIS

SYSTEM BOARD

Clock Circuitry

The 14.745 MHz clock drive for the System Module digital circuitry is derived from a gate oscillator circuit comprised of inverters U21C and U21D, 14.7456 MHz crystal Y1 and associated components. Resistor R110 keeps the inverter gate U21CV in the linear mode during power up for reliable clock start up. Resistor R111 and capacitor C3 provide AC and DC drives to Y1. Inverter U21D buffers the clock signal and transistors Q11 and Q12 allows microprocessor U1 to adjust the clock frequency.

When the microprocessor pulls P4.5 (Pin 60) low, Q11 and Q12 are turned on. Capacitors C52 and C53 are then switched into the circuit, changing the capacitive loading on Y1. This change causes the oscillation frequency to change approximately 300 PPM.

Reset and Watchdog Timer

The System Board contains a power up/manual reset circuit to initialize the programmed code and hardware devices on the board. The reset circuitry, consisting of digital supervisory circuit U19, monitors the +5V line. When the voltage on the +5V line is below +4.5V, U19 outputs a low going pulse on Pin 15. At the same time it also outputs a high going pulse on Pin 16. Manual reset is also possible by pulling the reset line on J1-18C low. This is accomplished through the reset switch S1 on the Power Module. Supervisory circuit U19 also provides added protection for EEPROM U6 to ensure data integrity. If the +5V line falls below 4.65V, U19 inhibits any chip select to U6 that might occur during power transients.

In addition, U19 provides a watchdog timer. The microprocessor must pulse U19, Pin 11 periodically or U19 will generate a reset. The microprocessor pulses the watchdog timer using U1, Pin 40 (**WDOG**).

The reset pulse is applied to microprocessor U1, Programmable Peripheral Interface (PPI) U34 and to the backplane Board on J1-18C.

Address Latch

The main controller on the System Board is microcomputer U1 (80C152JB). The microcomputer obtains instructions from the program stored in EPROM U4.

The lower eight bytes of the address from the microcomputer multiplex between address and data. Address latch U2 (74HC37) is used to secure the address from the microcomputer using the microcomputer ALE signal (U1-55). The upper eight bits of the address contains only address information and are applied directly to the devices needing these additional lines.

Address Decoding

One of eight de-multiplexers U3 (74HC138) is used for address decoding. The three most significant bits of the address bus (A13, A14, A15) are used to select one of eight, 8k-byte blocks of data (non-program) memory.

The microprocessor PSEN output signal at U1-54 is used to disable demultiplexer U3. This event causes all of the eight select outputs to go high so only the program EPROM U4 will be selected during accesses of program memory. This prevents bus contention on the AD lines. The following devices are mapped to an 8k-byte block of data memory:

U3-15	0000-1FFFH	EEPROM (U6)
U3-12	2000-3FFFH	RAM (U5)
U3-13	4000-5FFFH	Digital Signal
		Processor

U3-12	6000-7FFFH	Input/Output
		Latches (U7,
		U25)
U3-11	8000-9FFFH	82C54 Counter
		Timer (U29)
U3-10	A000-17	82C55
		Programmable Peripheral
		Interface (U34)
U3-9	C000-DFFFH	not used
U3-7	E000-FFFFH	not used

Program/Data Memory

Three memory components are included on the System Board: UV EPROM U4, static RAM U5 and EEPROM U6. The microprocessor can address two 64k-byte memory segments; the program memory and the data memory. The program memory is stored in U4 and is selected by a low going pulse on microprocessor PSEN output U1-54.

The low going pulse on the PSEN output disables access to any data memory by disabling address decoder U3. This disables all chip selects to devices mapped to data memory locations (Refer to Address Decoding section for more information on devices mapped into data memory space).

The microprocessor executes program instructions fetched from EPROM U4. The microprocessor outputs the program address on AD[0:7] and A[8:15]. The address latch latches the address on AD[0:7] when ALE goes high. The EPROM inputs the 16 bit address and outputs the eight bit instruction found at the input address on AD[0:7] lines when PSEN goes low.

Data memory is stored in static RAM U5. Data can be written to and read from this device. However, all data is lost at power off. The RAM inputs the latched address output by the microprocessor when chip enable input U5-20 from address decoder U3 is low. If the RAM OE input U5-22 goes low, then the data contained in the RAM at the input address is output to the microprocessor on the AD[0:7] lines. If the RAM WE input U5-27 goes low, data on AD[0:7] is stored in the RAM at the input address.

Personality information is stored in EEPROM U6. Data can be written to and read from this device. Data stored in this device is not lost at power off. The EEPROM inputs the latched address from the microprocessor when the CE input is low. The chip enable input is generated by address decoder U3 and output on U3-15. However, the signal is routed through U19.

Supervisory circuit U19 disables the EEPROM chip enable when the board is in a reset condition. This ensures that no extraneous writes occur to the EEPROM during power-up or brown out conditions which could affect personality data.

If EPROM OE input U5-22 goes low while the CE is low, then data contained in the EEPROM at the input address is output to the microprocessor on the AD[0:7] lines. If EEPROM WE U5-27 goes low while the CE is low, then data on AD[0:7] is stored in the EEPROM at the input address.

Counter Timer IC

Counter timer U29 consists of three 16-bit timer/counters that are used for the different functions described below. The microprocessor can enable, disable and configure the counters, as well as read back counter status information using the AD bus. The input clock to the device is derived by dividing by two the 14.7456 MHz clock signal out of gate oscillator buffer U21D using D flip-flop U28. This same 7.3725 MHz clock signal is used for each counter/timer to give 135 ns resolution.

Counter 0 is used for Channel Guard decoding. It is configured to output a 135 ns pulse on U29-12 at eight times the Channel Guard decode frequency. This pulse is latched by flip-flop U18A. The output of this latch is applied to the INTO input of microprocessor U1-16, causing an interrupt. The microprocessor resets the latch, clearing the interrupt by pulsing U18A, Pin 4 using P1.6 (U1-10) output in the interrupt service routine.

The 135 ns pulse on U29-12 also causes a sample of the limited Channel Guard signal LIM_CG to be taken. This sample is brought into the microprocessor during the INTO service routine on P4.7 (U1-58) and used for Channel Guard decoding.

The second counter timer (counter 1) is used to generate a microprocessor interrupt. This interrupt is used by the microprocessor to generate Channel Guard and should occur at eight times the Channel Guard frequency. The counter is configured to send the output (U29-16) high upon timing out. This high is inverted by NPN transistor Q9 and resistors R1 and R18.

The inverted signal is then applied to the microprocessor INT1 input (U1-18) which causes an interrupt to occur. The counter is reloaded by the interrupt service routine software. This causes U29-16 to return low which clears the interrupt.

The third counter/timer (Counter 2) is used for tone generation. When a tone is desired, the microprocessor configures the counter/timer to output a square wave on U29-20 at the desired frequency. This square wave is then bandpass filtered by active filter stages U17C and U17D to remove undesired harmonics and to create a sine wave.

A resistor divider consisting of resistors R38 and R39 sets the level of the sine wave at U17-14 to approximately 800 mVrms. The microprocessor disables the counter/timer when no tone is desired.

Programmable Peripheral Interface

Programmable Peripheral Interface (PPI) U34 provides three additional eight bit I/O ports. The reset generated by supervisory circuit U19 is input on U34-39 and serves to reset the U19 to the default state. Ports A and C are configured as output ports and Port B as an input port.

Port C outputs are used to load the Rx and Tx synthesizers as well as provide serial communications with the interface board. Port A outputs provide an interface to the GETC in GETC equipped stations. The system board loads the synthesizers and communicates with the interface board with the following Port C signals: RXF4/AUX2 (DATA), RXF2 (ENABLE), TXF1 (A0), TXF2 (A2), RXF1 (A2), and from Port A: SERIAL CLK (CLK). The remaining Port A and Port C inputs are used for several different interfaces.

Port B inputs several interface signals. Pull up resistors to +5V are used on all open collector type inputs. These signals are then buffered and/or level shifted where appropriate. Resistors are put in series with all of the inputs for spike protection.

Where level shifter/buffer U41 is not used, dual diodes are included to prevent over or under voltage conditions.

The RUS input uses NPN transistor Q4 to convert the signal to CMOS logic levels.

Additional I/O

Additional I/O is provided by input latch U25 and output latch U7. Each of these latches is mapped to address 6000H. However, input latch U25 is enabled by a low pulse on the microprocessor RD output while the output latch U7 is enabled by a low pulse on the microprocessor WR output.

The input latch is used to get DC CNTRL, BATT STDBY, REM PTT, TX DISABLE, CG MON and M3_STATUS signals onto the AD bus so they can be read by the microprocessor. The DC control currents are decoded elsewhere in the system and the decode current is passed to the microprocessor using DC CNTRL1, DC CNTRL2, and DC CNTRL3 inputs. These are CMOS level signals so no level shifting is required.

The BATT STDBY signal requires level shifting to convert the 22-volt high to a TTL level. This is achieved by resistors R4 and R5. Dual diode D2 limits the signal to be within -0.7 and +5.7 to guard against over or under voltage conditions. BATT STDBY is driven high when the station is operating from battery power.

Output latch U7 (74HC377) latches the data on the AD bus when the chip is selected by address decoder U3 and a low

going WR pulse is received. This latched data goes into analog switch select lines used to select audio paths in the analog circuitry.

Microprocessor I/O

The microprocessor has some additional I/O pins. These pins are used to bring signals in and out of the microprocessor directly without going through any additional I/O devices such as latches or a PPI. The LOCAL PTT input is level shifted and buffered by U41E and brought into the microprocessor on U1-19.

The microprocessor also generates he AUX RX MUTE output used to mute an auxiliary receiver. The signal originates on U1-51 and is inverted by U26F. This gives an open collector active low output.

The EXT LSD SEL, LINE IN SEL, LSACQ, and 4W DUPLEX signals are also generated by the microprocessor. These signals go to the analog circuitry and control audio routing through analog switches.

The microprocessor is also capable of loading electronic potentiometers U35 and U36. Each of these potentiometers contains two 256-position variable resistors. The microprocessor must serially load all four variable resistors at the same time.

The microprocessor switches the potentiometers select line (U1-17) high. This enables the electronic potentiometer loading circuitry and allows the microprocessor to shift 34 bits of serial data into the electronic potentiometers, 17 bits of data into each IC.

Data is output on U1-20 and clocked into U35 and U36 on the rising edge of the clock signal generated by the microprocessor on U1-21. The microprocessor can also read back the current potentiometer settings.

When data is clocked into U35 and U36, the current potentiometer setting is clocked out and brought into the microprocessor on U1-22. After all 34 bits have been clocked into U35 and U36, the microprocessor pulls the potentiometer select line (U1-17) low. This ends the loading sequence, and causes the digital potentiometers to load the new resistance value.

A/D Converter

The system Board contains an A/D converter. This is used for metering DC inputs. Four external metering inputs are accommodated. These include PWR SNSR, TX MTR+ relative to TX MTR-, RX MTR+ relative to TX MTR-, and EXT ICK

The PWR SNSR input will accommodate a DC level between zero and +5V relative to analog ground. The input is protected from over voltage conditions by a dual diode D7.

The control shelf routes TX MTR + and TX MTR - into a differential amplifier consisting of U17A, and resistors R140, R142, R145, and R146. This amplifier removes any common-mode voltage. The output of this differential amplifier is actually measured and must be between zero and 2.9 volts.

RX MTR+ input is assumed to be between zero and +5V relative to analog ground. No conditioning is performed except for dual diode D3 that protects from over or under voltage conditions.

The EXT JCK input is designed to input signals between zero and +10V relative to AGND. Operational amplifier U17B provides a high impedance and buffers the input signal. The output of this amplifier goes through a voltage divider network composed of resistors R3 and R6 that divides the DC level by two. This signal is then routed to multiplexer U33.

Analog multiplexer U33 gates one of four inputs to the A/D converter U27. The microprocessor determines which input is selected using U1-52 and U1-57. The microprocessor starts an A/D conversion by putting a rising edge on U27-5. U27 then converts the DC input voltage selected on U33 to a digital value.

The converted digital value is clocked out of U27 sequentially by the microprocessor, beginning with the most significant bit. The microprocessor selects U27 by setting U27-5 low. When the A/D converter is selected, it puts the MSB of the eight bit conversion data on U27-6. This is read by the microprocessor. Successive data bits are clocked out of the A/D converter on falling edges of its CLK output (U27-7).

When all eight bits have been clocked out, the A/D is deselected, and the next conversion cycle begins by the microprocessor setting U27-5 high.

DSP Interface

System Board 19D903771G1 is equipped with plugs to accommodate **D**igital **S**ignal **P**rocessor (**DSP**) "**piggy back**" board 19D902667G1. This board plugs into J2 and J3 of the system board.

The microprocessor communicates with the DSP board through the eight bit AD[0:7] bus and a dual port RAM located on the DSP board. This memory is mapped into an 8k-byte data memory segment using address decoder U3. Data can be written to and read from any of the 256 byte locations that can be addressed by AD[0:7].

The DSP board contains an address latch to latch the address information on AD[0:7] when ALE goes high. When the DSP CS is low and the microprocessor WR output is low, the data on AD[0:7] is written into the latched DSP data memory segment address. When the DSP CS is low and the microprocessor RD output is low, data on AD[0:7] is read into microprocessor U1 from the latched DSP data memory segment address.

Two handshake lines used for the DSP interface for synchronization are DSP TBLF and DSP RBLE. When the DSP has written a message to the dual port RAM, it signals the microprocessor U1 by asserting DSP TBLF low. The microprocessor then reads the message from the dual port RAM and then resets DSP TBLF high to tell the DSP that it is ready for another message.

When the microprocessor wants to send a message to the DSP it first looks at he DSP RBLE input. A high on this input indicates that the DSP receive buffer is empty and it is ready to accept a new message. When the microprocessor has written the message to the dual port RAM, it asserts the DSP RBLE low to signal the DSP that it should read the new message. The DSP resets DSP RBLE high after it has read the message.

The microprocessor can reset the DSP board by setting U1-7 high. The high is inverted by Q10, and the resulting low resets the DP board.

RS232 Interface

The system Board has an RS232 serial port for programming and diagnostics. RS232 data is received on the PGM RXD input and is converted to TTL Levels by U22A. The TTL data is brought into microprocessor internal UART on U1-14. Transmit data is output on U1-15 by the microprocessor, and level shifted to RS 232 levels by U22B. The RS232 data is output on PGM TXD.

GSC Interface

A high speed serial interface that is referred to as a global serial channel (GSC) is also included on the system board. Data is transferred bidirectionally over an RS485 differential pair made up of COMM+ and COMM.

When the microprocessor wants to send data over the GSC, it enables the drivers in U24 by outputting a low on U1-6. Data is generated internally in the microprocessor and output on U1-5. The data is converted to RS485 levels and output on the GSC by U24.

The receiver section of U24 is always enabled so the microprocessor receiver can monitor the transmitted data. This monitoring is to check for collisions on the GSC created by multiple GSC nodes transmitting simultaneously. The drivers of U24 converts received data to TTL levels and outputs them on U24-1. The microprocessor brings the received data into its receiver on U1-4 for message decoding.

Transmitter Interface

In the 19D902590G3 and G1 system modules, the system board is responsible for loading the TX Synthesizer module with the proper frequency information. When the micro-controller sees a PTT from an enabled source, it first drives ANT RLY active. This switches the antenna switch in stations with this option and also applies power to the TX synthesizer oscillator circuit. Next, data is shifted into the TX Synthesizer using A2, A1, A0, CLK and DATA. After the TX Synthesizer has been loaded with the data, enable goes active to allow the TX Synthesizer PLL Circuit time to acquire frequency lock. At the end of this ENABLE period, the micro-controller samples the TX synthesizer status bit supplied by the Interface Board. If there is no fault (synthesizer locked) then the microprocessor drives the TX OSC CNTRL (PA KEY) active which turns on the RF PA. Upon reset, or a channel change, the system board must also set the PA Power pot by sending the appropriate data to the interface board. Audio for the transmission is output on the TX AUDIO HI and the TX AUDIO LO outputs. Channel Guard is summed into TX AUDIO HI.

The 19D902590G5 system module does not utilize its transmitter interface.

Receiver Interface

At power up or upon channel change, the RX Synthesizer is programmed in the same manner as the TX Synthesizer in all system modules. Carrier activity on the selected channel is sensed by the receiver squelch circuitry and applied to the System Module on the CAS input. This active high input is level converted by transistor Q8, and applied to the microprocessor on U1-23. The microprocessor then routes audio according to the receiver or station configuration programming.

Local Controls

The system board has three switches and LED's for local control. These switches and indicators have different functions according to the group of system module. In the 19D902590G3 and G1 system modules, switch S2 is a REMOTE PTT switch. A low on this input causes the microprocessor to react as though a PTT has been received over the line. The line is also routed to an external module to activate the remote PTT input. Switch S3 is a TX DISABLE switch. When S3 is active the microprocessor inhibits all transmissions.

In the 19D902590G5 system module, switch S2 is not used. A low on this input is ignored by the microprocessor. Switch S3 is a SQ DEFEAT switch. When S3 is active the microprocessor

unsquelches the receiver by setting the digital squelch pot on the interface board to zero.

All system boards are electrically equivalent. When not activated, S2 pulls the line to +5V. When activated, the switch pulls the line to ground. This switch is input on Pin 7 of input latch U25. In the case of S3, when not activated, resistor R136 pulls the line to +5V. When activated, the switch pulls the line to ground. This switch is input on Pin 8 of input latch U25.

In all system modules, switch S4 is a CG MONITOR switch. When not activated, resistor R137 pulls the line to +5V. When activated, the switch pulls the line to ground. This switch is input on Pin 9 of input latch U25. This line is also routed to the external connector. This allows an external module to activate the CG monitor input, or to examine the state of the CG MONITOR input. A low on this input causes the microprocessor to switch into Channel Guard monitor mode.

When the system module is in CG MONITOR, it lights LED DS3 by outputting a high on U1-66. This high is inverted by U2D. This allows current to flow through DS3, turning on the LED.

Putting the 19D902590G3 and G1 System Modules in the transmit disable mode lights LED DS2 by outputting a high on U1-67. This high is inverted by U26C. This allows current to flow through DS2, turning on the LED. In the 19D902590G5 System Module, this LED indicates a UN SQuelch condition.

The 19D902590G3 and G1 System Modules concurrently activate the ANT relay output and LED DS1. The LED indicates Transmit activity. In the 19D902590G5 System Module, this LED indicates that the System Module is in Local Programming Mode.

CG High Pass and De-emphasis Filters

Receiver audio is applied to the system module VOL/SQ HI port on J1-2B. U37A buffers the input signal and removes any DC bias. With an input of 1Vrms at 1000 Hz, the output is typically 2 Vrms and is supplied to three places: Channel Guard reject filter, DSP board through DSP unfiltered audio, and Channel Guard decode.

U30A is a unity gain notch filter, centered at 205 Hz. The filter provides 25dB of attenuation. U30B, U30C, and U30D form a sixth order unity gain high pass filter with a cut off frequency of 280 Hz. U37B is a $\pm 1/-3$ dB de-emphasis filter that rolls audio off at 6 dB/oct in the frequency range 300-3000 Hz.

With 1Vrms into VOL/SQ HI, the output of U37B will be 750 mVrms. This output is supplied to four places: U8A, TX Audio out, Line Audio out and the summing amplifier with the optional auxiliary receiver input. U8A is controlled by the mi-

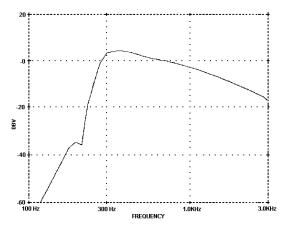
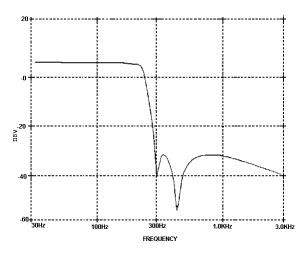


Figure 1 - Channel Guard Tone Reject (+1, -3 dBV)

Figure 2 - Channel Guard Tone Rejct Filter (+2, -8 dBV)



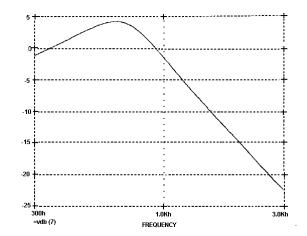


Figure 3 - Channel Guard Encode/Decode Filter

Figure 4 - Battery Alarm/Morse Code Band-Pass Filter

croprocessor to switch between MIC and VOL/SQ audio to the DSP. The combination of U37A, U30A, U30B, U30C, U30D, and U37B provides the frequency envelope shaping requirements (roll-off) as shown in figure 7.

The TX Audio Out circuit consists of U15, U36A, U8C, and U37D. IC U15 is an analog multiplexer that is controlled by the microprocessor. Any of the following signals may be connected to the TX AUDIO HI output: LOCAL MIC, VOL/SQ, DSP LINE/TX AUDIO, DSP TX AUDIO, External High Speed Data, LINE Input, open (battery alarm), and ground (for no transmission). U8C is an analog multiplexer controlled by the microprocessor to sum CG into the TX audio output and increase the TX Audio gain on U37D.

Battery Alarm/Morse Code is summed with the output of U15. This allows for the transmission of the alarm signal when other signals are present. U36 is a dual digital potentiometer controlled by the microprocessor, and adjusts the transmit audio level. U37D, a gain stage that drives the TX AUDIO HI (J1-5C) and TX AUDIO LO (J1-6C), is adjustable between 40 and 250 mVrms.

U37C is the +2/-8 dB de-emphasis filter that provides a 6 dB/oct roll off from 300-3000 Hz for the local intercom or speaker audio. With a rated input of 1Vrms at 1000 Hz, the output level of this filter is 750 mVrms. This filter in combination with U37A, U30A, U30B, U30C, and U30D provides the frequency response shown in Figure 8.

U32 is the analog multiplexer for the INTERCOM Audio output. It allows for selection of VOL/SQ audio, Line input audio, Voice Guard summing, and DSP LINE/TX AUDIO. Amplifier U31C sums the multiplexed audio with Voice Guard Tone. The resulting Signal is applied to J1-7A.

CG/LSD Decode Filter

Received audio is coupled through a low pass filter to remove the audio, leaving only Channel Guard (CG) or Low Speed Data (LSD) information. A hard limiter then converts the signal into a digital square wave. The square wave is decoded in software as well as the 135 degree phase shift for STE.

U9A is a gain stage that supplies two frequency dependent negative resistor (FDNR) circuits. The first FDNR consists of U10A and U10B, and has a cut off at 205 Hz. The second FDNR formed by U10C and U10D, has a cut of at 230 Hz.

U11B is a low pass filter that provides added attenuation in the 300-3000 Hz range. These elements combine to provide 35 dB of attenuation for frequencies above 310 Hz. The resulting frequency response is shown in figure 9.

U11A, D5, and Q2 combine to convert the analog signal at the U11B output to a 0-5 Vdc square wave. This square wave is then supplied to U18B to be read and decoded by the microprocessor.

CG/LSD Encode Filter

U12C is used to select between external Low Speed data or Walsh bits. The Walsh bits are created by the microprocessor on U1-64 and U1-65, and form a rough sine wave. This signal is coupled through U9C to provide some gain.

U16A, U16B, U16C, and U16D form two FNDR circuits that have the same response as described in the CG/LSD Decode Filter section. U9D provides gain and drives U35A. U35A is a digital potentiometer that provides level adjustment and is controlled by the microprocessor. Also, U9B has a 3.3 K-ohm source impedance to allow a separate source to drive Channel Guard HI. This filter has the same response as shown in Figure 9.

Battery Alarm / Morse Code

The Battery Alarm / Morse Code tones are generated using U29, U17C and U17D. U29 is a clock timer that creates a square wave at the required frequency. Capacitor C113 and resistor R39 form a high pass filter to provide DC blocking. U17C is a second order low pass filter and U17D provides gain. These components combine to provide the response shown in figure 10.

The output of U17D sources the signal to U31B and U15. U15 is the TX Audio multiplexer discussed earlier in this section. U31B is an amplifier to sum the Battery Alarm signal with the Voice guard alert tone, which is then transferred to the LINE output.

Line Audio and Compression

The LINE output circuitry consists of U14, U8B, U36B, U31D, U13B, and U31A. The analog multiplexer U14 is used to connect one of the following signals to the line driver U31D: LOCAL MIC, VOL/SQ, auxiliary receiver, aux receiver/VOL/SQ, DSP LINE/TX audio, MODEM LINE data, open or ground. The open state is to transmit Battery alarm or Voice Guard alarm.

U31A sums the auxiliary receiver audio with the VOL/SQ audio. U36 B is a digital potentiometer and controls the audio level into the line driver U31D. The level at LINE A (J1-4B) and LINE B (J1-4A) is adjustable between -20 dBm and +11 dBm

The LINE IN Audio is selected from LINE A and LINE B in a two wire system, and from DUPLEX LINE A and DUPLEX LINE B in a four wire system. Each input has a 600

ohm impedance to match the line impedance. U12B selects between two and four wire audio.

In MASTR IIe systems digital potentiometer U35B sets the level applied to the line compensation filter U13B. This filter can be set up to compensate for high frequency roll off on long lines by removing R16. This modification should be used when roll-off in the 2500 to 3000 Hz range is more than 10 dB below the 400 to 600 Hz level.

Following U13B is the compression circuit consisting of U13C, U13D, D6 and Q3. LINE IN audio from U13B is applied to a network composed of transistor Q3, and resistors R65, R75, and R76. After being amplified by U13C, the output is applied to four places: LINE output, TX Audio output, Intercom audio, and D6.

This compensation circuit is only effective in stations using Group 1 system modules (no DSP), or Group 2 system modules programmed for DC Control. For all other applications, audio routing bypasses the compensation filter.

The output of amplifier U13C is rectified by D6 which charges capacitor C25. U13D amplifies the voltage on C25 and provides a DC offset to the gate of FET Q3. FET Q3 serves as a variable resistor in the voltage divider composed of R65 and Q3 which limits the input to U13C. R75 and R76 serve to reduce the distortion across the voltage divider.

This circuit normally operates in a linear fashion with Q3 turned off which appears as a high resistance. When higher than normal audio is received at U13B, the amplification of U13C is rectified by D6, increasing the voltage across C25.

The increased voltage across C25 through U13D starts turning on Q3 reducing the drain to source resistance, which in turn, lowers the audio to U13C. Since this affects not only the output of U13C, but the turn on voltage of Q3 from U13D, a steady audio output is provided.

-NOTE -

The compressor can be disabled by removing Q3. The compressor is typically disabled when shipped from the factory. It is preferable to use the compressor function on the DSP board. If the hardware compressor is used install Q3 (19A703795P1; sim to 4416) on System Board 19D903771G1

DSP BOARD

The Digital Signal Processing (DSP) Board utilizes both digital and analog integrated circuits (IC's) to offer a compact,

flexible, and reliable solution for audio signal analysis and modification. Most of the components are surface mounted.

The DSP Board operates with two channels of audio. It conditions audio inputs, digitizes the audio, and processes the audio data in software. The DSP Board then sends the transformed audio to analog outputs and the signal analysis information to its digital output.

Audio inputs from the system board are DSP FILT VOL/SQ, DSP UNFILT VOL/SQ, and DSP LINE IN. These signals are selected and conditioned through U10, U11, and U15. These signals are then sampled and digitized by U4 and U5. The digital audio data is then applied to U1 for processing. After processing, the audio data is then returned to U4 and U5 for digital to analog Conversion. The transformed audio is applied to the System Board on DSP TX AUDIO and DSP LINE/TX AUD.

All pertinent information from DSP analysis of the audio is communicated digitally to the system board through the dual port RAM U12. Messages are written to this memory space by the DSP microcomputer, U1. The messages are read from the memory by the System Board (via the digital signals of connector P3).

For clarity, the DSP circuitry is analyzed in the following order:

- 1) DSP and supporting circuitry
- 2) Analog input/output
- 3) Parallel communication port

DSP Microprocessor

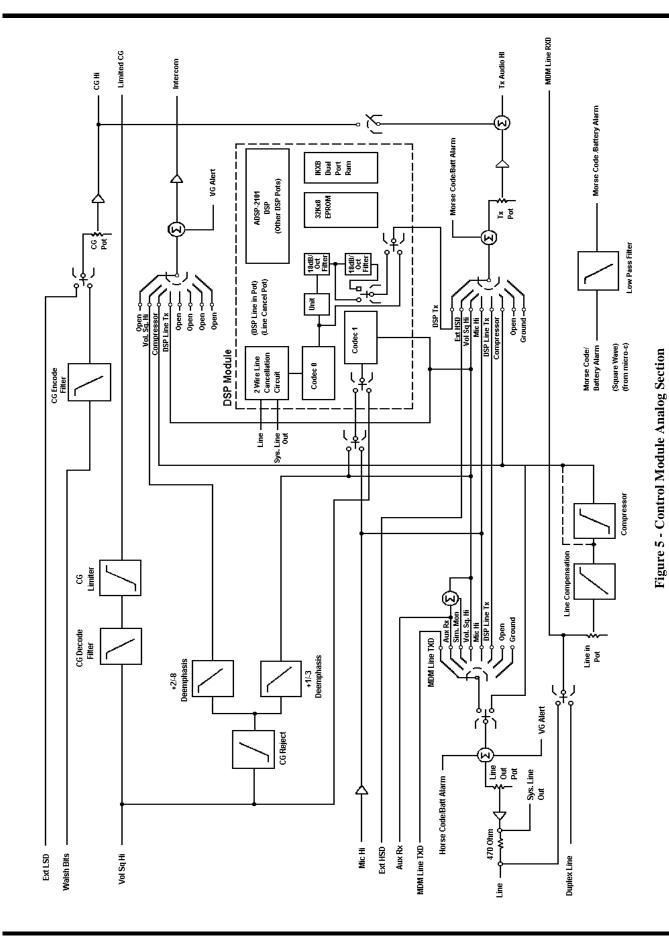
The DSP Board performs its functions in the ADSP-2101 Digital Signal Processing microcomputer, U1. This chip requires external hardware to function.

Crystal Y1 provides the 8.192 MHz clock required by the DSP microprocessor. Capacitors C16 and C17 provide the loading required for reliable startup and stable oscillation.

DSP microprocessor, U1, operates form a 2K internal program memory. This program RAM is volatile; it is lost during power off sequences. Therefore, it is necessary to have non-volatile memory to safely hold the DSP Board Code. The 16K X 8 EPROM (U6) performs this function.

Upon reset, or during "re-boot," up to 2K X 24 of internal program memory is loaded from this external "BOOT EPROM." The BOOT EPROM, U6, holds up to eight different pages that can be loaded. The selection of a 2K-page of code is software controlled except during reset when boot page zero is always loaded.

In essence, boot memory page is loading a sequence of read cycles. The BMS pin goes low in order to enable the boot



memory chip. Addresses are sequenced on lines A0 through A13, D22 and D23. The /RD pin activates the data bus, D15 through D8, for each transfer of program memory into internal program memory space.

The boot EPROM circuitry also includes resistors R1 and R2. These resistors are zero ohms, and are the equivalents to jumper wires. If the capability of eight boot pages is necessary, R2 is removed and R1 is installed in the board. In this case, U6, Pin 1 acts as an extra address pin that is connected to D23. If the capability of four boot pages is necessary, R1 is removed and R2 is installed on the board. In this case, U6, Pin 1 acts as a program pin and is tied off to five volts.

Analog inputs

The DSP Board inputs and processes audio both from the receiver and the line simultaneously. There are two possible receiver input settings and two possible line audio input settings. These are:

- 1) DSP FILT VOL/SQ
- 2) Two wire line input or four wire line input.

This audio selection is actuated directly by the DSP but is user programmable. The DSP uses the address multiplexer, U8, to select U7, a D flip flop register. This is accomplished by setting A13-A11 to binary 100 when /PMS goes low. Such a sequence will cause U8, Pin 14 to go low, enabling data to pass through the D flip flops upon /WR going low and then high. D8 and D9 are written to the outputs of U7 (Pins 2 and 5) as VOL/SQ SEL and CANCEL SEL.

Depending on these signals, digitally controlled analog switches (U10) route the appropriate signals to achieve the final audio input setting described above. If VOL/SQ SEL is a logic low, DSP FILT VOL/SQ is selected. If CANCEL SEL is a logic high, four wire audio is selected. If not a logic high, two wire audio is selected.

Each audio channel selection requires proper voltage level adjustment to insure an optimal conversion to the digital domain where it will be processed. This conversion is performed by codecs U4 and U5. In other words, the audio signals are conditioned to assure that their dynamic ranges can be accommodated by the codecs. The codecs will neither be under driven nor saturated. This results in a digital signal with uniform Signal to Noise Ratio (SNR) following the A/D conversion.

Filtered Receiver input conditioning

Filtered receiver input comes from the System Board following de-emphasis channel guard reject filtering at a maximum of 1.16 Vrms. This input channel requires no amplification to assure that codec U4 utilizes the dynamic range efficiently.

The amplification factor is determined by resistors R5 and R6. The gain is one. Therefore, the maximum input to the codec is 1.16 Vrms.

Four Wire Line Input Conditioning

Line input comes from the DPLX line input pair of the control shelf when it is in a four wire configuration. Its audio is not in contention with audio leaving the station because there are two lines independently dedicated for the output signal.

The line audio level adjustment is able to attenuate a 2.47 Vrms (+11 dBm) signal and amplify a 77.3 mVrms (-20 dBm) signal to the maximum input level of the codec (approximately 1.4 Vrms). This is to compensate for up to 30 dB of line loss that can occur between the remote control unit and the station.

In the four wire configuration, DSP LINE IN is propagated to TP1 with only a gain of 1.09 provided by the differential instrumentation circuit of U11 (A, B, C) and resistors R12-17. This occurs because the amount subtracted from DSP LINE IN is AGND (U10A, Pin 13).

Between TP1 and TP2 there is a digitally controlled variable gain stage. The gain stage is composed of U11D, U15 (1), and resistors R18 and R20. The DSP addresses (and serially loads) a resistance from 0 to 10K ohms into the dual programmable potentiometer, U15. The digitally controlled impedance, along with R18 and R20, form a gain through operational amplifier U11D.

The DSP uses address multiplexer U8 to select U7, a D flip flop register. This is accomplished by setting A13-11 to binary 100 when /PMS goes low. Such a sequence will cause U8, Pin 14 to go low, enabling data to pass through the D flip flops upon /WR going low and then high.

Data is written to the D10, D11 and D15 outputs of U7 (Pins 6, 9 and 19) known as POT CLK, POT LOAD EN, and POT IN. POT IN is serial data. POT LOAD EN is a serial load enable. During a load cycle, POT LOAD EN is held high. Seventeen POT IN values are set up and held with respect to the rising edges of POT CLK. The first value loaded into the dual programmable potentiometer is a "don't care" value. The following sixteen values comprise two 8-bit wiper positions. Wiper 1 gets loaded before wiper 0. Loading is specified from MSB to LSB.

Two Wire input line conditioning

Two wire line input comes from the Line input of the system board when it is in a two wire configuration. This audio is in contention with audio which is leaving the station on the same two wire pair. The DSP Board must cancel out the interfering output audio from the input. In addition, it must

LBI-38764G ASSEMBLY DIAGRAM

amplify the input signal to account for the line loss of up to 30 dB that can occur between the remote control unit and the station.

Cancellation of transmit audio from receive audio on the two wire pair is accomplished by differential instrumentation amplifier of U11 (A, B, C) and resistors R11-17 and the DSP-controlled resistance through U15(0) and R10. The SYSBD LINE OUT (a DSP Board input signal) is limited by U18A and level adjusted through the programmable potentiometer, U15(0), (as explained above) and then subtracted from the line input signal.

After subtraction, the remaining input (line audio) is level adjusted by the remaining programmable potentiometer U15(1) exactly as in the four wire case.

DSP Analog Outputs

The Rx output of codec U5, TX CODEC RX, passes through U16-B for pre-emphasis and hard limiting. Limiting action occurs when the instantaneous AC voltage exceeds the DC bias set by resistors R34, R36, and R37, at which point D1 becomes forward biased placing it in the feedback loop of U16-B. Due to the V-I characteristics of the diode, limiting action occurs. U16-B also provides +6 dB/oct pre-emphasis for transmitted audio in the 300 to 3000 Hz band. The pre-emphasis meets the EIA standard of +1/-3 gain flatness in the passband.

Following the pre-emphasis and the limiter, U16-C forms a third order low pass filter stage required by FCC regulations to filter the harmonics created by the preceding limiter. R35 and C29 compose a passive first order low pass filter while active filter U16-C provides an additional two poles for this filter stage. Following U16-C is another filter stage consisting of a second order passive low pass filter and a second order active low pass filter built around U16-D.

Analog switch U17 selects which filter stage output, if any, is routed to the transmitter. Depending upon the transmit frequency band, the FCC requires different filter characteristics for the post limiter filter. The output of analog switch U17-B DSP TX AUD is routed to P2-7 where it connects to the System Board.

The Rx output of U4 pin 2 DSP LINE/TX AUD is routed to P2-8 where it connects to the System board. This audio output typically dives the line out circuits on the system board.

Parallel Communications Hardware

The DSP Board is equipped with a full duplex parallel interface for communications between the system board microprocessor and the DSP microprocessor chip. Communications are accomplished through the dual port RAM, U12.

Byte wide messages are passed between system board and DSP chip by reading and writing data upon this common piece of memory.

The external eight bit system microprocessor can read and write to the dual port RAM. Address latch U13 (74HC373) is used by the 8 bit host to latch the address (AD7-AD0). The host uses its ALE signal to perform the actual clocking into the

Once ALE has returned to logic one, AD7-AD0 become bi-directional data pins. During a "write" cycle, the host sets up data on AD7-AD0. During a "read" cycle, the system board microprocessor releases the data lines AD7-AD0 into their high impedance state.

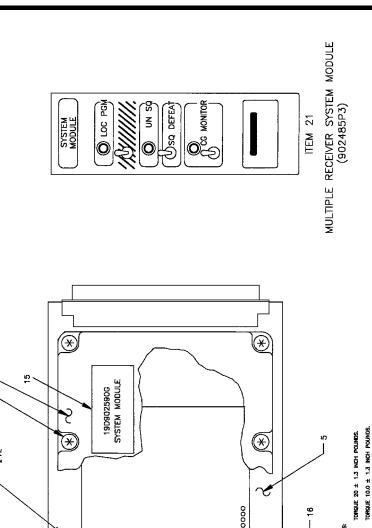
Finally, the System Board low-going /UPRD or /UPWR pulse executes the desired read/write function. Note that reading and writing are only accomplished when the DSPCS signal is held low. In this way, the system board microprocessor exclusively selects the dual port memory space to prevent contention upon the multiplexed address and data bus.

The DSP chip reads and writes from the dual port RAM by first selecting its communication memory space. This is accomplished by setting A13-11 to binary 010 when PMS goes low. Such a sequence will cause U8, Pin 13 to go low and thus enable dual port RAM, U12. Once enabled, the communications memory is accessed with address lines A9-A0 and data lines D15-D8, in conjunction with a low-going /RD and /WR

The DSP chip (U1) and host processor coordinate message handling through the RBLE and TBLF flags. The DSP chip sets TBLF by writing to location 3FFH of the dual port RAM.

Similarly, the host microprocessor can clear TBLF by reading from location 3FFH of the dual port RAM. It then sets RBLE by writing to location 3FEH of the dual port RAM. (Note that the flag is set when it is low; it is clear when it is high.) This way, both the microprocessors can monitor flag conditions in order to keep from trying to access the same locations in memory at the same time.

Tri-state buffer U9 is used by the DSP microprocessor in order to read the RBLE and TBLF flags. This alleviates the possibility of contention on the DSP data bus D15-D8. The RBLE and TBLF flags are read by first selecting U9. This is accomplished by setting A13-A11 to binary 100 when /PMS goes low. Such a sequence will cause U8 pin 14 to go low and thus enable data to pass through the tri-state buffer upon /RD going low. U9, Pins 2 and 3 appear on D8 and D9, and are latched into U1 when /RD returns high.



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SHELF SYSTEM (902485P1)

ITEM 2

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19D902590G1, G3 & G5

(*) #

(19D902590, Sh. 1, Rev. 4)

SYSTEM MODULE

PARTS LIST LBI-38764G

SYSTEM MODULE

19D902590G1 - M IIe System Module 19D902590G3 - M IIe/M III System Module with DSP 19D902590G5 - M III System Module (Used in Multiple Receiver Applications)

(Used in Multiple Receiver Applications)				
SYMBOL	PART NO.	DESCRIPTION		
2	19D902485P1	Chassis.		
3	19D902486P1	Cover.		
4	19D902555P1	Handle.		
5 6	19D903771G1 19A702381P506	System Board (See Below). Screw, thread forming: TORX, No. M3.5-0.6 X 6.		
7	19A702381P513	Screw, thread forming: TORX , No. M3.5-0.6 X 13.		
8	19B232682P20	Spacer: Pad.		
9	19A702381P508	Screw, thread forming: No. 3.5-6.0 x 8.		
15	19B235310P1	Nameplate.		
12	19A701431P1	Silicone Compound.		
15	19B235310P1	Nameplate, Blank.		
16	19D902667G1	DSP Module, MIIe/MIII (See Below).		
21	19D902485P3	Casting, System Module Auxiliary Receiver.		
		SYSTEM BOARD 19D903771G1/G2		
		CAPACITORS		
C1	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.		
C2	19A702052F3			
C3	19A702052F14	Ceramic: 0.01 μF ±10%, 50 VDCW.		
C4	19A7020517 15	Ceramic: 10 pF ±10%, 50 VDCW, temp. coef 0 ±30 PPM/°C.		
C5	19A702052F3	Ceramic: 1000 pF ±10%, 50 VDCW.		
C6	19A702052F26	Ceramic: 0.1 μF ±10%, 50 VDCW.		
and	.5/1/020021 117	Ceramic: 0.01μF ±5% 50 VDCW.		
C7	4047050555			
C8	19A705205P5	Tantalum: 6.8 μF, 10 VDCW; sim to Sprague 293D.		
C9	19A702052P28	Ceramic: 0 .022 μF ±10%, 50 VDCW.		
C10 and	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.		
C11				
C12	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.		
C13	19A705205P2	Tantalum: 1 μF, 16 VDCW; sim to Sprague 293D.		
C14	19A705205P6	Tantalum: 10 μF, 16 VDCW; sim to Sprague 293D.		
C15	19A702052P124	Ceramic: 0.068 μF,. ±5% 50 VDCW.		
C16	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.		
C17	19A705205P2	Ceramic: 1 µF, 16 VDCW; sim to Sprague 293D.		
C18	19A702052P24	Ceramic: 0.068 μF,. ±10% 50 VDCW.		
C19	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.		
C21	19A702061P77	Ceramic: 470 μF,. ±5% 50 VDCW, temp coef 0 ±30 PPM/°C.		
C22	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.		
C23	19A702052P26	Ceramic: 0.1 μF ±10%, 50 VDCW.		
C25	19A705205P111	Tantalum: 47 μF ±10%,, 10 VDCW; sim to Sprague.		
C27	19A705205P111	Tantalum: 47 μF ±10%,, 10 VDCW; sim to Sprague.		
and C28				
C29	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.		
thru	10/11/02/02/10	Ceramic. 1000 pr ±1070, 30 VDGVV.		
C36	4047000			
C38	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.		
C39	19A705205P5	Tantalum: 6.8 μF, 10 VDCW; sim to Sprague 293D.		
C40	19A705205P6	Tantalum: 10 μF, 16 VDCW; sim to Sprague 293D.		
C42 thru	19A705205P6	Tantalum: 10 μF, 16 VDCW; sim to Sprague 293D.		
C45				
C46	344A3431P1	Monolithic: 1.0 μF +80/-20%, 16 VDCW.		
C47	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.		
C49	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.		
and				
C50	10.4.70205254.4	O		
C51	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.		
C52	19A702061P37	Ceramic: 33 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°C.		
C53	19A702061P45	Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°C.		
C59 and	19A702052P122	Ceramic: 0.047 μF ±5% 50 VDCW.		
C60				
C61	19A702052P26	Ceramic: 0.1 μF ±10%, 50 VDCW.		
C62	19A149791P1	Metalized Polypropylene: 0.22 ± 1%, 50 VDCW.		
thru C67				
C67	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.		
thru	.5/1/020021 17	σειαιτικ. σ.στ μι ±10 /0, σο ν DC νν.		
C71				
C72 and	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.		
C73				

*COMPONENTS, ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	PART NO.	DESCRIPTION
C74	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
thru	10711 020021 11	Geranic. 0.01 μι ±1070, 30 VBOVV.
C78	4047000500444	0 : 004 5 :50/ 50//50//
C79	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.
C80 thru	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
C84		
C87	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
thru		
C95		
C96 thru	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
C98		
C99	19A702052P5	Ceramic: 1000 pF ±10% 50 VDCW.
C100	19A702052P14	Ceramic: 0.01 μF ±10%, 50 VDCW.
and		σοιαιποι σιο τ μι =1070, σο τ 20τι
C101		
C102	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
C103	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.
C104	19A705205P111	Tantalum: 47 μF ±10%, 10 VDCW; sim to Sprague.
C105	19A702052P5	Ceramic: 1000 pF ±10%, 50 VDCW.
thru C108		
C108	19A702052P14	Coromics 0.04E 1409/ F0 V/DC/W
and	19A702032F14	Ceramic: 0.01 μF ±10%, 50 VDCW.
C110		
C111	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.
C112	19A702061P77	Ceramic: 470 μF,. ±5% 50 VDCW, temp coef0 ±30 PPM/°C
C113	19A702052P114	Ceramic: 0.01μF ±5% 50 VDCW.
		DIODES
5.4	40470005050	
D1 thru	19A700053P2	Silicon: 2 Diodes in Series; sim to BAV99.
D8		
DS1	19A703595P10	Optoelectric: Red; sim to HP HLMP-1301-010.
thru		,
DS3		
		CONNECTORS
J1	19B801587P7	DIN: 96 male contacts, right angle mounting; sim to AMP
		650887-1.
J2	19A704852P334	printed wire board.
and		
J3		
		INDUCTORS
L1	19A705470P53	Coil, Fix, Surf Mt, 220 ±H.
and L2		
LZ		TRANSISTORS
		TRANSISTORS
Q2	19A700076P2	Silicon: NPN; sim to MMBT3904, low profile.
Q4 _.	19A700076P2	Silicon: NPN; sim to MMBT3904, low profile.
and Q5		
Q6	344A3855P1	Silicon: NPN; sim to PZT2222A.
Q7	19A700076P2	Silicon: NPN; sim to MMBT3904, low profile.
Q8	19A700059P2	Silicon: PNP; sim to MMBT3904. low profile.
Q9	19A700076P2	Silicon: NPN; sim to MMBT3904, low profile.
and		
Q10		
Q11	19A700059P2	Silicon: PNP sim to MMBT3904, low profile.
and Q12		
		RESISTORS
D.4	40D065555	
R1	19B800607P10	Metal Film: 10K ohms ±5%, 1/8w.
R2	19B800607P473	Metal Film: 47K ohms ±5%, 1/8w.
R3	19A702931P301	Metal Film: 10K ohms ±1%, 200 VDCW, 1/8w.
R4	19B800607P153	Metal Film: 15K ohms ±5%, 1/8W.
R5	19B800607P332	Metal Film: 3.3K ohms ±5%, 1/8W.
R6	19A702931P301	Metal Film: 10K ohms ±1%, 200 VDCW, 1/8w.
R7	19A702931P249	Metal Film: 3160 K ohms ±1%, 200 VDCW, 1/8w.
R8	19A702931P313	Metal Film: 13.3K ohms ±1%, 200 VDCW, 1/8w.
R9	19B800607P103	Metal Film: 10K ohms ±5%, 1/8W.
R10	19B800607P391	Metal Film: 390 ±5%, 1/8W.
R11	19B800607P562	Metal Film: 5.6K ohms ±5%, 1/8W.
R12	19B800607P103	Metal Film: 10K ohms ±5%, 1/8W.
R13	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8W.
R14	19B800607P272	Metal Film: 2.7K ohms ±5%, 1/8W.
R15	19B800607P103	Metal Film: 10K ohms ±5%, 1/8W.
R16	19B800607P103	Metal Film: 10K onms ±5%, 1/8vv. Metal Film: Jumper.
R17	19A702931P369	Metal Film: 51.1K ohms ±1%, 200 VDCW, 1/8w.
R18	19B800607P103	Metal Film: 10K ohms ±5%, 1/8W.
R19	19B800607P102	Metal Film: 1K ohms ±5%, 1/8W.
R20	19B800607P103	Metal Film: 10K ohms ±5%, 1/8W.
	19B800607P223	Metal Film: 22K ohms ±5%, 1/8W.
R21		
R22 R23	19B800607P102 19B800607P103	Metal Film: 1K ohms ±5%, 1/8W. Metal Film: 10K ohms ±5%, 1/8W.

SYMBOL	PART NO.	DESCRIPTION
R24	19B800607P122	Metal Film: 1.2K ohms ±5%, 1/8w.
R25	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R26	19A702931P384	Metal Film: 73.2K ohms ±1%, 200 VDCW, 1/8w.
R27	19A702931P388	Metal Film: 80.6K ohms ±1%, 200 VDCW, 1/8w.
R28	19A702931P358	Metal Film: 39.2K ohms ±1%, 200 VDCW, 1/8w.
R29	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R30	19A702931P384	Metal Film: 73.2K ohms ±1%, 200 VDCW, 1/8w.
R31	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R32	19A702931P369	Metal Film: 51.1K ohms ±1%, 200 VDCW, 1/8w.
R33 R34	19A702931P325	Metal Film: 17.8K ohms ±1%, 200 VDCW, 1/8w.
R35	19A702931P350 19A702931P383	Metal Film: 32.4K ohms ±1%, 200 VDCW, 1/8w.
R36	19A702931F363 19A702931F382	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R37	19A702931F382	Metal Film: 69.8K ohms ±1%, 200 VDCW, 1/8w. Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R39	19A702931P40	Metal Film: 100K ohms ±1%, 200 VDCW, 1/8w.
R40	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R41	19B800607P104	Metal Film: 100K ohms ±5%, 1/8w.
R42	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R43	19B800607P684	Metal Film: 680K ohms ±5%, 1/8w.
R44	19B800607P473	Metal Film: 47K ohms ±5%, 1/8w.
R45	19B800607P683	Metal Film: 68K ohms ±5%, 1/8w.
R46	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R47	19B800607P681	Metal Film: 680 ohms ±5%, 1/8w.
R48	19B800607P681	Metal Film: 680 ohms ±5%, 1/8w.
R49	19A702931P301	Metal Film: 10K ohms ±1%, 200 VDCW, 1/8w.
R50	19A702931P388	Metal Film: 80.6K ohms ±1%, 200 VDCW, 1/8w.
R51	19B800607P472	Metal Film: 4.7 ohms ±5%, 1/8w.
R52	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R53	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w. ±5%, 1/8w.
R54	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R55	19B800607P472	Metal Film: 4.7K ohms 5%, 1/8w.
R56	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R57 and	19B800607P1	Metal Film: Jumper.
R58		
R59	19B800607P102	Metal Film: 1K ohms ±5%, 1/8w.
R60	19B800607P471	Metal Film: 470 ohms ±5%, 1/8w.
R61	19A702931P413	Metal Film: .133K ohms ±1%, 200 VDCW, 1/8w.
R62	19A702931P327	Metal Film: 18.7K ohms ±1%, 200 VDCW, 1/8w.
R63	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R64	19A702931P177	Metal Film: 619 ohms ±1%, 200 VDCW, 1/8w.
R65	19B800607P682	Metal Film: 6.8K ohms ±5%, 1/8w.
R66	19A702931P243	Metal Film: .2740 ohms ±1%, 200 VDCW, 1/8w.
R67	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R68	19B800607P153	Metal Film: 15K ohms ±5%, 1/8w.
R69	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R70	19B800607P104	Metal Film: 100K ohms ±5%, 1/8w.
R71	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R72	19A702931P269	Metal Film: 5110 ohms ±1%, 200 VDCW, 1/8w.
R73 R74	19A702931P313	Metal Film: 13.3K ohms ±1%, 200 VDCW, 1/8w.
R74 R75	19B800607P561	Metal Film: 560 ohms ±5%, 1/8w.
R75 and	19B800607P224	Metal Film: 220K ohms ±5%, 1/8w.
R76		
R77	19A702931P376	Metal Film: 60.4K ohms ±1%, 200 VDCW, 1/8w.
R78	19A702931P222	Metal Film: 1650 ohms ±1%, 200 VDCW, 1/8w.
R79	19B800607P561	Metal Film: 560 ohms ±5%, 1/8w.
R80 and	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R81		
R82	19B800607P562	Metal Film: 5.6K ohms ±5%, 1/8w.
R83	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R84	19A702931P389	Metal Film: 82.5K ohms ±1%, 200 VDCW, 1/8w.
R85	19A702931P434	Metal Film: 221K ohms ±1%, 200 VDCW, 1/8w.
R86	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R87	19B800607P105	Metal Film: 1M ±5%, 1/8w.
R88	19A702931P305	Metal Film: 11K ohms ±1%, 200 VDCW, 1/8w.
R89	19A702931P384	Metal Film: 73.2K ohms ±1%, 200 VDCW, 1/8w.
R90	19A702931P358	Metal Film: 39.2K ohms ±1%, 200 VDCW, 1/8w.
R91	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R92	19A702931P384	Metal Film: 73.2K ohms ±1%, 200 VDCW, 1/8w.
R93	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R94	19A702931P388	Metal Film: 80.6K ohms ±1%, 200 VDCW, 1/8w.
R95	19A702931P325	Metal Film: 17.8K ohms ±1%, 200 VDCW, 1/8w.
R96	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R97	19A702931P382	Metal Film: 69.8K ohms ±1%, 200 VDCW, 1/8w.
R98	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R99	19A702931P350	Metal Film: 32.4K ohms ±1%, 200 VDCW, 1/8w.
R100	19B800607P471	Metal Film: 470 ohms ±5%, 1/8w.

SYMBOL	PART NO.	DESCRIPTION
R102	19B800607P563	Metal Film: 56K ohms ±5%, 1/8w.
R103	19B800607P123	Metal Film: 12K ohms ±5%, 1/8w.
R104	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R105	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R106	19A702931P355	Metal Film: 36.5K ohms ±1%, 200 VDCW, 1/8w.
R107	19A702931P285	Metal Film: 7500 ohms ±1%, 200 VDCW, 1/8w.
R108	19A702931P177	Metal Film: 619 ohms ±1%, 200 VDCW, 1/8w.
R109	19B800607P102	Metal Film: 1K ohms ±5%, 1/8w.
R110	19B800607P105	Metal Film: 1M ohms ±5%, 1/8w.
R111	19B800607P102	Metal Film: 1K ohms ±5%, 1/8w.
R112	19A702931P401	Metal Film: 100K ohms ±1%, 200 VDCW, 1/8w.
and	10/1/020011 401	Wetarriim. Took orims ±1 /8, 200 v DCvv, 1/6w.
R113		
R114	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R115	19B800607P391	Metal Film: 390 ohms ±5%, 1/8w.
and R116		
R116	19B800607P391	Motel Film: 200 ohmo ±59/ 1/9w
		Metal Film: 390 ohms ±5%, 1/8w.
R117	19A702931P385	Metal Film: 75.0K ohms ±1%, 200 VDCW, 1/8w.
R120	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R143	19A702931P436	Metal Film: 232K ohms ±1%, 200 VDCW, 1/8w.
R144	19A702931P243	Metal Film: 2740 ±1%, 200 VDCW, 1/8w.
R145	19B800607P224	Metal Film: 220K ohms ±5%, 1/8w.
R146	19B800607P474	Metal Film: 470K ohms ±5%, 1/8w.
R147	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R148	19B800607P153	Metal Film: 15K ohms ±5%, 1/8w.
R149	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
thru		
R151		
R152	19B800607P102	Metal Film: 1K ohms ±5%, 1/8w.
R153	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R155	19A702931P434	Metal Film: 221K ohms ±1%, 200 VDCW, 1/8w.
R156	19A702931P406	Metal Film: 113K ohms ±1%, 200 VDCW, 1/8w.
R157	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R158	19A702931P383	Metal Film: 71.5K ohms ±1%, 200 VDCW, 1/8w.
R159	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R160	19A702931P177	Metal Film: 619 ohms ±1%, 200 VDCW, 1/8w.
R161	19B800607P103	Metal Film: 10K ohms ±5%, 1/8w.
R162	19B800607P474	Metal Film: 470K ohms ±5%, 1/8w.
R163	19B800607P102	Metal Film: 1K ohms ±5%, 1/8w.
R164	19B800607F172	The state of the s
		Metal Film: 4.7K ohms ±5%, 1/8w.
R165	19B800607P682	Metal Film: 6.8K ohms ±5%, 1/8w.
R166	19A702931P355	Metal Film: 36.5K ohms ±1%, 200 VDCW, 1/8w.
R167	19A702931P325	Metal Film: 17.8K ohms ±1%, 200 VDCW, 1/8w.
R168	19A702931P305	Metal Film: 11K ohms ±1%, 200 VDCW, 1/8w.
R169	19A702931P393	Metal Film: 90.9K ohms ±1%, 200 VDCW, 1/8w.
R170	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R171	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
R172	19B800607P474	Metal Film: 470K ohms ±5%, 1/8w.
R173	19B800607P474	Metal Film: 470K ohms ±5%, 1/8w.
R174	19A702931P313	Metal Film: 13.3K ohms ±1%, 200 VDCW, 1/8w.
R175	19B800607P333	Metal Film: 33K ohms ±5%, 1/8w.
R176	19A702931P222	Metal Film: 1650 ohms ±1%, 200 VDCW, 1/8w.
R177	19A702931P269	Metal Film: 5110 ohms ±1%, 200 VDCW, 1/8w.
R178	19B800607P474	Metal Film: 470K ohms ±5%, 1/8w.
R179	19A702931P385	
R180	19A702931F363	Metal Film: 75.0K ohms ±1%, 200 VDCW, 1/8w.
		Metal Film: 133K ohms ±1%, 200 VDCW, 1/8w.
R181	19A702931P130	Metal Film: 200 ohms ±1%, 200 VDCW, 1/8w.
R183	19B800607P183	Metal Film: 18K ohms ±5%, 1/8w.
R186	19B800607P472	Metal Film: 4.7K ohms ±5%, 1/8w.
		SWITCHES
SW2	19A705959P3	Switch: toggle: SPDT, 0.4A @ 20 volts; sim to
thru	13/1/0030373	C&K T101-M-H9-A-B-E.
SW4		
		INTEGRATED CIRCUITS
U1	19A705982P101	Microcomputer: 8-bit extended I/O; sim to
110	4047004745000	INTEL 80C152JB-1.
U2	19A703471P302	Digital: Octal Data Latch; sim to 74HC373.
U3	19A703471P320	Digital: 3-Line to 8-Line Decoder; sim to 74HC138.
U4	344A3307G16	PROM Kit, MIIe/MIII.
U5	19A705603P6	Digital: 8K X8 bit Static CMOS SRAM; sim to
LIC	1047020525122	K M6264AL-10.
U6	19A703952P102	EEPROM: 2kX8, 5 Volt, programmable: sim to XICOR X28116CP-20.
U7	19A704380P319	Digital: CMOS Octal Data Flip-Flop; sim to 74HC377
U8	19A704360F319	Digital: Triple 2-channel Analog Multiplexer; sim to
-00	13/11/02/11/03/53	4053BM.
U9	344A3070P3	Digital: JFET, Input Quad Operational Amplifier; sim
		TL074.
		The state of the s
U10	19A704883P2	Digital: Quad Operational Amplifier; sim to MC3303.

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SYMBOL	PART NO.	DESCRIPTION
U12	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer; sim to 4053BM.
U13	19A704883P2	Digital: Quad Operational Amplifier; sim to MC3303D.
J14	19A702705P3	Digital: Microprocessor System Supervisor.
15	344A3856P101	CMOS Analog Multiplexer; sim to DG408D.
116	19A704883P2	Digital: Quad Operational Amplifier; sim to MC3303D.
ind		
J17		
J18	19A704380P302	Digital: CMOS Dual Data Flip-Flop; sim to 74HC74.
J19	19A149895P1	Digital: Supervisory Circuit; sim to MAXIM MAX691C.
J20	19A116180P575	Digital: Hex Open Collector Inverter; sim to 7406.
J21	19A703995P3	Digital: High speed logic, hex inverter, unbuffered sim to 74HCU04.
122	344A3039P201	Digital: Driver/Receiver, EIA-232DN.28; sim to MC145406
24 25	19A705980P101 19A703471P316	Tranxceiver, Differential Bus; sim to SN751768. Digital: Driver/Receiver, octal 3-state non inverting buffer; sim to 74HC541.
J26	19A116180P575	Digital: Hex Open Collector Inverter; sim to 7406.
J27	19A705979P101	Digital: CMOS A/D; sim to TL549CP.
128	19A704380P302	
128	19A704380P302 19A149466P301	Digital: CMOS Dual Data Flip-Flop; sim to 74HC74. Digital: CH MOS, Programmable timer; sim to
		INTEL 82C54.
J30 J31	19A704883P2 344A3070P3	Digital: Quad Operational Amplifier; sim to MC3303D. Digital: JFET, Input Quad Operational Amplifier;
133	10470270502	sim to TL074.
132 nd	19A702705P3	Digital: 8-Channel Analog Multiplexer; sim to 4051BM.
133		
134	19A705991P101	Digital: Programmable interface; sim to Harris C82C55A.
J35	344A3041P201	Digital: Dual in-line potentiometers, ceramic, hermetically
ind		sealed; sim to DS1267S-10.
J36		
37	19A704883P2	Digital: Quad Operational Amplifier; sim to MC3303D.
40	19A116180P575	Digital: Hex Open Collector Inverter; sim to 7406.
J41	19A700176P101	Digital: Hex Inverting Buffer/Converter; sim to 4049UBD.
:U4	19A705840P2	Socket: sim to Amp 643646-3.
		CRYSTAL
1	19A702511G37	Crystal Assembly: 14.7456 MHz.
		DIGITAL SIGNAL PROCESSOR
	404700050500	19D902667G1/G2
1 ru	19A702052P26	Ceramic: 0.1 μF ±10%, 50 VDCW.
15		
16	19A702061P29	Ceramic: 22 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°C
nd		25.3
17		
18	19A705205P6	Tantalum: 10 μF, 16 VDCW; sim to Spraque 293D.
ru		
22	1047000505407	O
24	19A702052P107	Ceramic: 2200 pF ±5%, 50 VDCW.
25	19A702061P53	Ceramic: 68 pF ±5%, 50 VDCW.
26	19A702052P120	Ceramic: 0.033 μF ±5%, 50 VDCW.
27	19A705205P19	Tantalum: 2.2 μF ±20%, 10 VDCW; sim to Spraque 293D.
nd an		
28	1047000505101	0
29	19A702052P134	Ceramic: 0.1 μF ±5%, 25 VDCW.
30	19A702052P112	Ceramic: 6800 pF ±5%, 50 VDCW.
31	19A702052P105	Ceramic: 1000 pF ±5% 50 VDCW.
32	19A702052P142	Ceramic: 0.082 μF ±5% 50 VDCW.
00		· ·
,33	19A702052P112	Ceramic: 6800 pF ±5% 50 VDCW.
nd	19A702052P112	Ceramic: 6800 pF ±5% 50 VDCW.
C33 and C34		
and 034 035	19A702052P105	Ceramic: 1000 pF ±5% 50 VDCW.
nd :34 :35		Ceramic: 1000 pF ±5% 50 VDCW.
nd 334 335	19A702052P105	Ceramic: 1000 pF ±5% 50 VDCW.
nd 234 235 238	19A702052P105 19A702061P45	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES
nd :34 :35 :38	19A702052P105	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99.
nd :34 :35 :38	19A702052P105 19A702061P45	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES
nd 34 35 38 1	19A702052P105 19A702061P45	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99.
nd 34 35 38 1	19A702052P105 19A702061P45 19A700053P2	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99CONNECTORS
nd 34 35 38 1	19A702052P105 19A702061P45 19A700053P2	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 Pin.
nd :34 :35 :38 :11 :2 nd :3	19A702052P105 19A702061P45 19A700053P2 19A704779P14	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS
nd 334 335 338 01 01 22 nd 33	19A702052P105 19A702061P45 19A700053P2 19A704779P14	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper.
nd (334) (335) (335) (338) (311)	19A702052P105 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper.
nd 134 135 138 11 2 12 14 15	19A702052P105 19A702061P45 19A700053P2 19A704779P14	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper.
nd 34 35 38 1 1 2 nd 3 2 4 4 5 5 nd	19A702052P105 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper.
nd 334 335 338 11 2 2 13 3 2 2 4 4 15 16 6	19A702052P105 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper. Metal Film: 68K ohms ±5%, 1/8 w.
nd 334 335 338 11 2 nd 3 2 2 4 4 5 5 nd 6 6	19A702052P105 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683 19B800607P1	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°C
nd 334 335 338 338 338 338 338 338 338 338 338	19A702052P105 19A702061P45 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper. Metal Film: 68K ohms ±5%, 1/8 w. Metal Film: Jumper. Metal Film: Jumper. Metal Film: Jumper. Metal Film: 508K ohms ±5%, 1/8 w.
nd 334 335 338 338 338 338 338 338 338 338 338	19A702052P105 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683 19B800607P1	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°C
and 334 335 338 338 331 331 331 331 331 331 331 331	19A702052P105 19A702061P45 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper. Metal Film: 68K ohms ±5%, 1/8 w. Metal Film: Jumper. Metal Film: Jumper. Metal Film: Jumper. Metal Film: 508K ohms ±5%, 1/8 w.
nd 334 335 338 311 32 338 311 32 33 33 33 34 34 34 34 34 34 34 34 34 34	19A702052P105 19A702061P45 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683 19B800607P1 19B800607P682 19B800607P1	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper. Metal Film: 68K ohms ±5%, 1/8 w. Metal Film: Jumper.
nd 334 335 338 311 32 338 32 34 35 36 37 37 37 37 37 37 37 37 37 37 37 37 37	19A702052P105 19A702061P45 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper. Metal Film: 68K ohms ±5%, 1/8 w. Metal Film: Jumper. Metal Film: Jumper. Metal Film: Jumper. Metal Film: 508K ohms ±5%, 1/8 w.
and (1334) (1335) (1336) (1	19A702052P105 19A702061P45 19A702061P45 19A700053P2 19A704779P14 19B800607P1 19B800607P1 19B800607P683 19B800607P1 19B800607P682 19B800607P1	Ceramic: 1000 pF ±5% 50 VDCW. Ceramic: 47 pF ±5% 50 VDCW, temp coef 0 ±30 PPM/°CDIODES Silicon: sim to BAV99CONNECTORS Plug: 15 PinRESISTORS Metal Film: Jumper. Metal Film: Jumper. Metal Film: 68K ohms ±5%, 1/8 w. Metal Film: Jumper.

SYMBOL	PART NO.	DESCRIPTION
R17	19A702931P401	Metal Film: 100K ohms ±1%, 200 VDCW, 1/8 w.
R18	19B800607P201	Metal Film: 200 ohms ±5%, 1/8 w.
R20	19B800607P392	Metal Film: 3.9K ohms ±5%, 1/8 w.
R21	19B800607P103	Metal Film: 10K ohms ±5%, 1/8 w.
thru R27		
R28	19B800607P102	Motel Film: 1K ohmo ±E9/ 1/9 w
and	190000077102	Metal Film: 1K ohms ±5%, 1/8 w.
R29		
R30	19A702931P418	Metal Film: 150K ohms ±1%, 200 VDCW, 1/8 w.
R31	19A702931P318	Metal Film: 15K ohms ±1%, 200 VDCW, 1/8 w.
R32	19A702931P209	Metal Film: 12.1K ohms ±1%, 200 VDCW, 1/8 w.
R33	19A702931P369	Metal Film: 51.1K ohms ±1%, 200 VDCW, 1/8 w.
R34	19A702931P331	Metal Film: 20.5K ohms ±1%, 200 VDCW, 1/8 w.
R35	19A702931P201	Metal Film: 1000 ohms ±1%, 200 VDCW, 1/8 w.
R36	19A702931P317	Metal Film: 14.7K ohms ±1%, 200 VDCW, 1/8 w.
R37	19A702931P331	Metal Film: 20.5K ohms ±1%, 200 VDCW, 1/8 w.
R38	19A702931P377	Metal Film: 61.9K ohms ±1%, 200 VDCW, 1/8 w.
R39	19A702931P307	
		Metal Film: 11.5K ohms ±1%, 200 VDCW, 1/8 w.
R40	19A702931P347	Metal Film: 30.1K ohms ±1%, 200 VDCW, 1/8 w.
R41 and	19A702931P157	Metal Film: 383 ohms ±1%, 200 VDCW, 1/8 w.
R42		
R43	19A702931P339	Metal Film: 24.9K ohms ±1%, 200 VDCW, 1/8 w.
R44	19A702931P347	Metal Film: 30.1K ohms ±1%, 200 VDCW, 1/8 w.
R45	19A702931P30	Metal Film: 11.5K ohms ±1%, 200 VDCW, 1/8 w.
R46	19A702931P294	Metal Film: 9.31K ohms ±1%, 200 VDCW, 1/8 w.
R47	19A702931P265	Metal Film: 4640 ohms ±1%, 200 VDCW, 1/8 w.
R48	19A702931P294	
_		Metal Film: 9.31K ohms ±1%, 200 VDCW, 1/8 w.
R49	19A702931P201	Metal Film: 1000 ohms ±1%, 200 VDCW, 1/8 w.
R50 and	19A702931P201	Metal Film: 1000 ohms ±1%, 200 VDCW, 1/8 w.
R51		
R55	19A702931P301	Metal Film: 10K ohms ±1%, 200 VDCW, 1/8 w.
R56	19A702931P339	Metal Film: 24.9K ohms ±1%, 200 VDCW, 1/8 w.
R57	19A702931P301	Metal Film: 10K ohms ±1%, 200 VDCW, 1/8 w.
		INTEGRATED CIRCUITS
		INTEGRATED CIRCUITS
U1	344A3038P101	Digital: DSP Microcomputer, Operating Freq. 40.96
U4	19A705827P1	sim to ADSP210KX-40. Encoder/Decoder: sim to Texas Instruments
and	19470302771	TCM29C23.
U5		10M20020.
U6	344A3309G5	PROM Kit, MIIe/MIII.
U7	344A3064P203	Digital: HI-SPEED, octal D type Flip-Flop, pos. edge
		trig.; sim to 74HCT377.
U8	344A3064P201	Digital: HI-SPEED, 3-8 line decoder /demultiplexer,
110	244420645204	inverting; sim to 74HCT138.
U9	344A3064P204	Digital: HI-SPEED, octal buffer/line driver, 3-stage; sim to 74HCT541.
U10	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer;
3.0	10/11 0/21 0/0F J	sim to 4053BM.
U11	19A704883P2	Digital: Quad Operational Amplifier; sim to
		MČ3303D.
U12	344A3040P201	Digital: SRAM, 1K X 8 Dual port; sim to
		IDT7130SA100.
U13	344A3064P202	Digital: HI-SPEED, transparent Latch, 3-state;
U15	344A3041P201	sim to 74HCT373.
013	344A3041F201	Digital: Dual in-line potentiometers, ceramic, hermetically
		sealed; sim to DS1267S-10.
U16	344A3070P3	Digital: JFET Input quad Operational Amplifier;
		sim to TL074.
U17	19A702705P5	Digital: Triple 2-Channel Analog Multiplexer;
1110	2444207002	sim to 4053BM.
U18	344A3070P3	Digital: JFET Input quad Operational Amplifier; sim to TL074.
		CRYSTAL
	19A702511G30	Crystal, quartz: 8.192 MHz.
X1		
X1		SOCKETS
X1 XU1 XU6	19B235688P1 19A705840P2	SOCKETS Socket: PLCC. Socket: sim to Amp 643646-3.

PRODUCTION CHANGES

Changes to the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by those revisions.

System Module - 19D902590G2

To standardize production of MASTR IIe and MASTR III System Modules, changed MASTR IIe System Board from 19D902453G1

MASTR IIe System Board was: 19D902453G1 (see LBI-38639 for a description of this board).

System Board - 19D902771G1

To improve operation, changed R57 from 19B800607P472 (4.7K

ohms) to 19A702931P305 (11k ohms).

To make MASTR IIe and MASTR III System Boards compatible, changed R127 from 19A702931P269 (5.11K ohms) to Rev. B:

19A702931P401 (100K ohms).

Rev. C: To enhance audio routing by supplying CAS in the System Module in auxiliary receiver applications. Changed the following

Changed R24 from 19B800607P822 (8.2K ohms) to

19B800607P272 (2.7K ohms).

Changed R57 from 19B702931P305 (11K ohms) to

19B8800607P1 (Jumper).

Changed R82 from 19B800607P103 (19K ohms) to

19B800607P562 (5.6K ohms).

To improve performance, changed R24 from 19B800607P272 Rev. D:

(2.7K ohms) to 19B800607P122 (1.2K ohms).

In order to meet the 10% variance of the complete audio path. Rev. E: Changed the following capacitors:

Changed C79 from 19A702052P14 (±10%) to 19A702052P114

Changed C103 from 19A702052P14 (±10%) to 19A702052P114 (±5%).

To eliminate speaker audio oscillation, added R79 (19B800607P561) 560 ohms in series between C39 (+) and Rev. F:

J1-A7.

Digital Signal Processor - 19D902667G1

Rev. A-C: Incorporated into initial shipment.

Rev. D: To invert SYSBD Line in to accommodate 2-wire line audio cancellation, added C36-C38, D2, R50-R54, R56, R57, and

U18. Changed C29 and deleted R155.

C29 was: 19A702052P26, 0.1 µF 10%, 50 VDCW.

Rev. E: To adjust analog signal levels to protect hardware from excessive signal levels, changed R50, R51, and R53 and

Deleted U2 and U3.

Changed R50 from 19A702931P265 (4640 ohms) to

19A702931P201 (1.0K ohms).

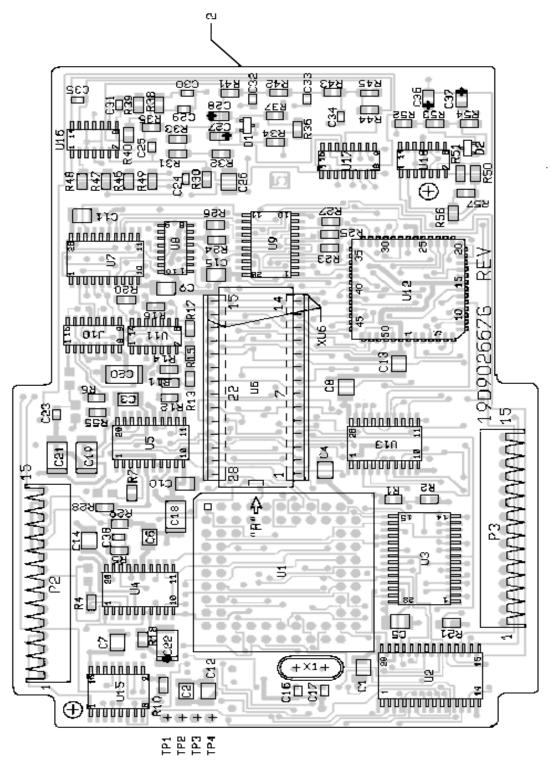
Changed R51 from 19A702931P265 (4640 ohms) to

19A702931P201 (1.0K ohms).

Changed R53 from 19A702931P305 (11K ohms) to

19A702931P265 (4640 ohms).

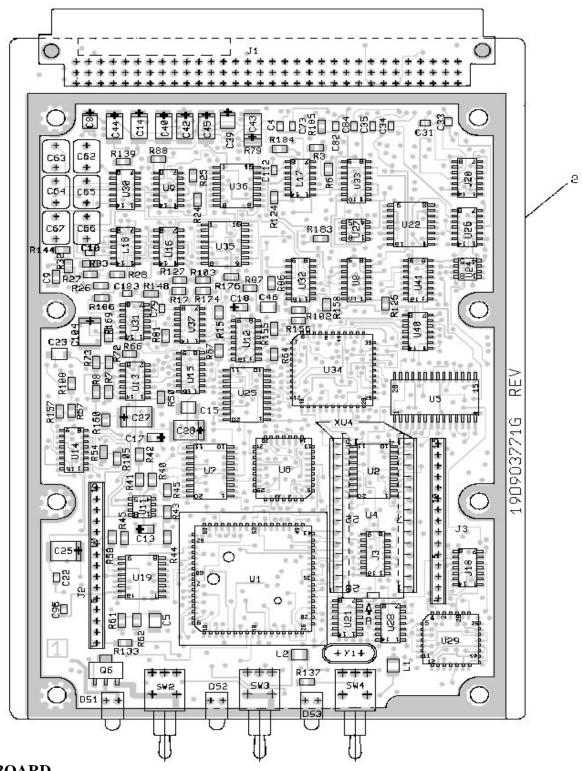
COMPONENT SIDE

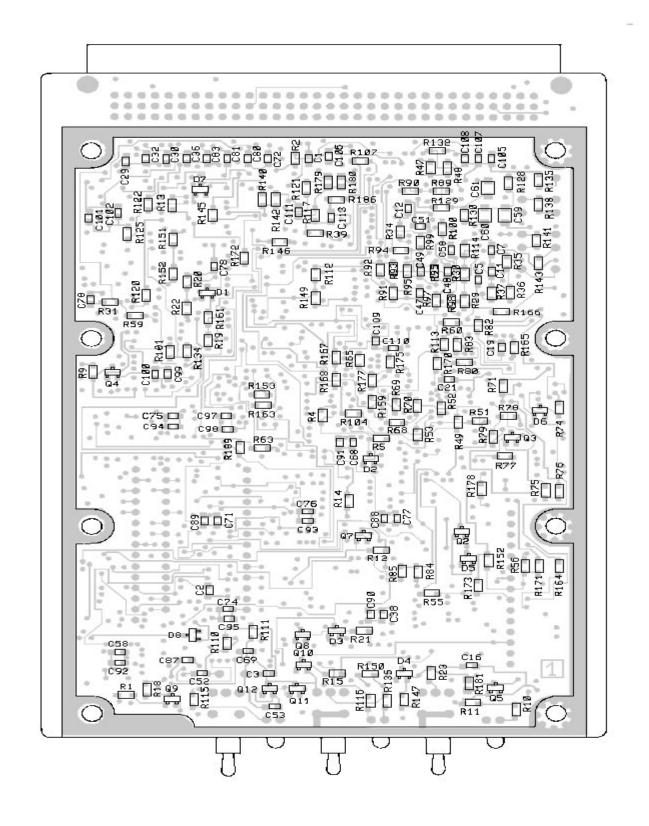


DSP BOARD 19D902667G1

(19D902667, Sh. 1, Rev. 5) (19D902668, Layer 1, Rev. 5) LBI-38764G OUTLINE DIAGRAM

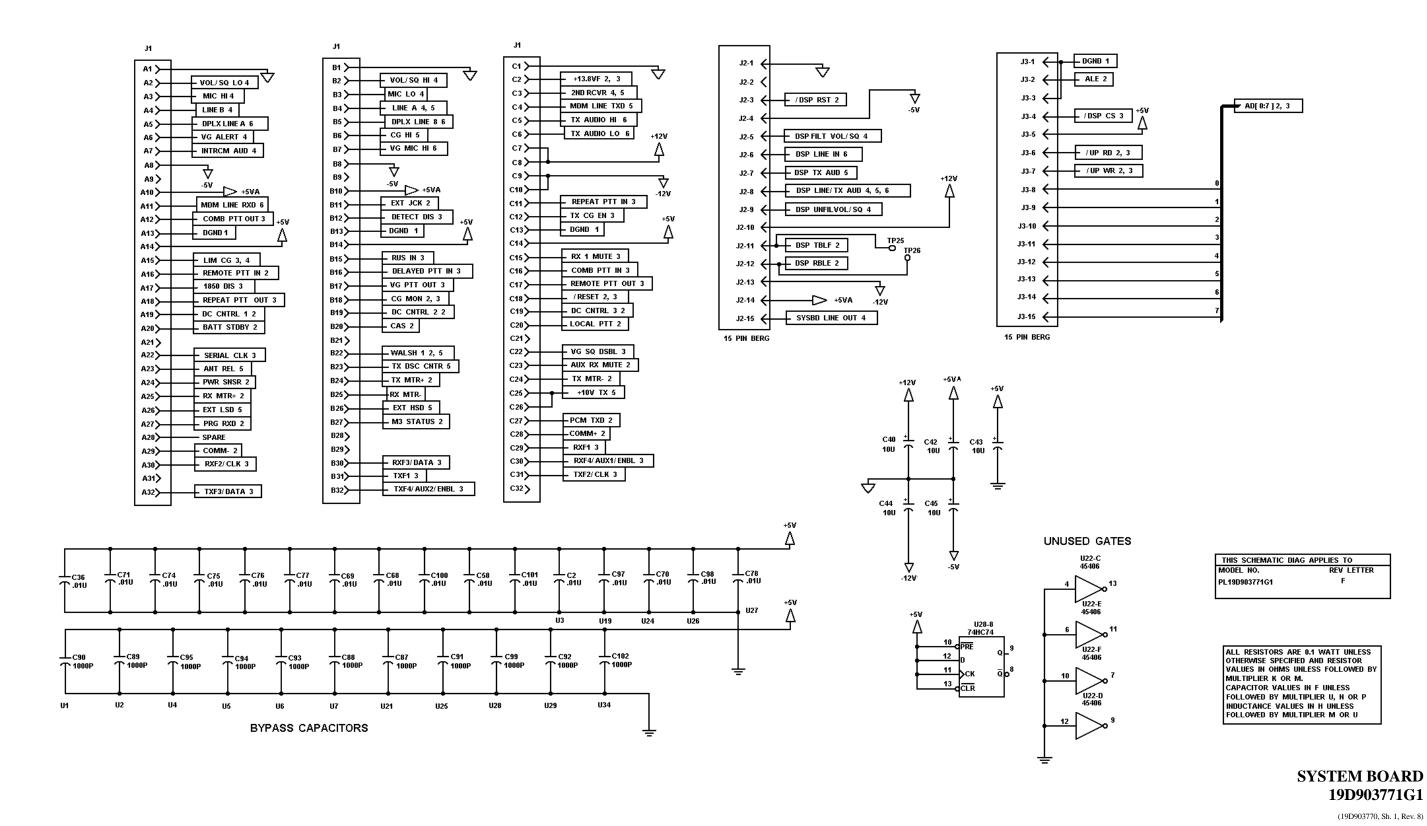
COMPONENT SIDE SOLDER SIDE

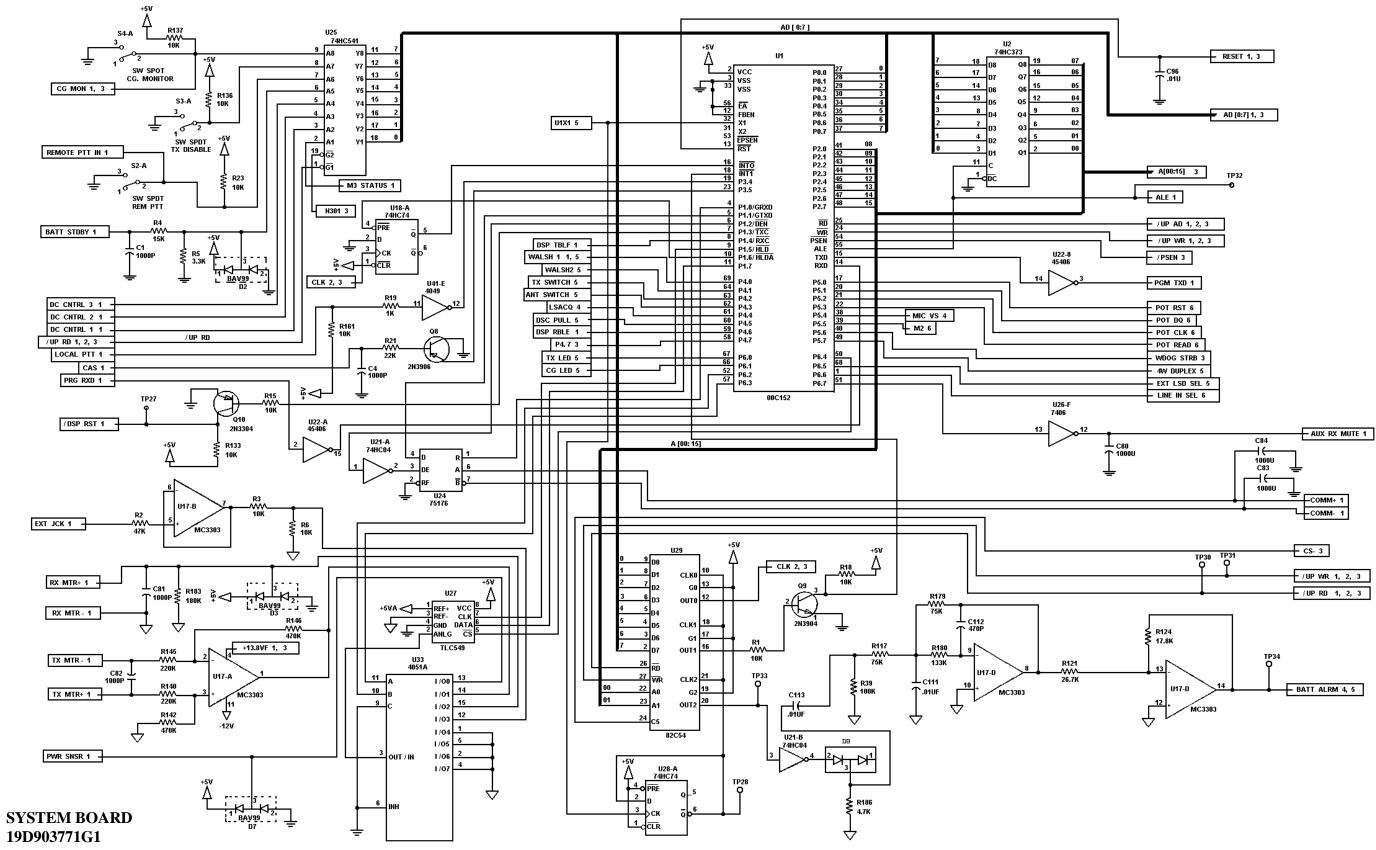




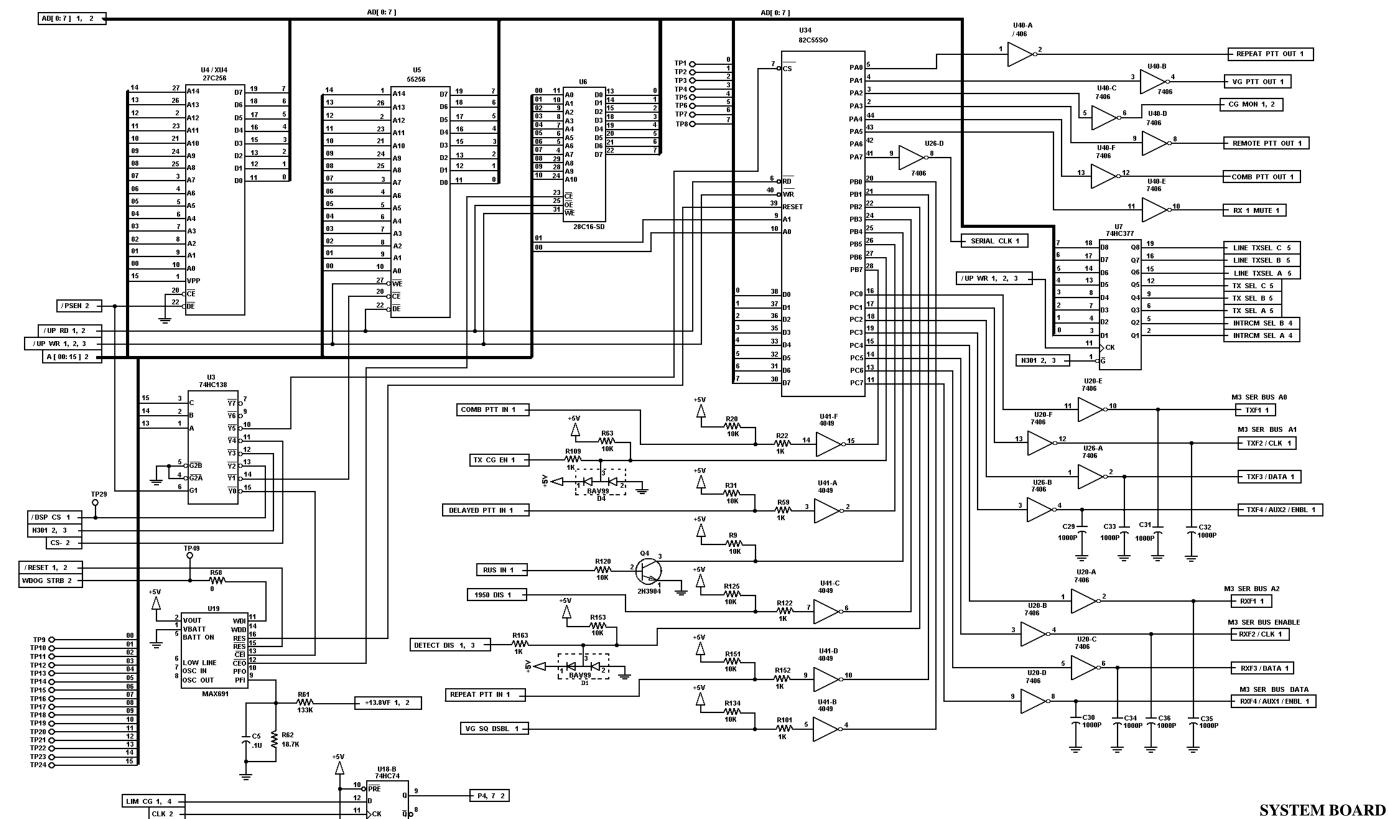
SYSTEM BOARD 19D903771G1

(19D903771, Sh. 1, Rev. 3) (19D903772, Layer 1, Rev. 1A) (19D903772, Layer 6, Rev. 1A) SCHEMATIC DIAGRAM LBI-38764G



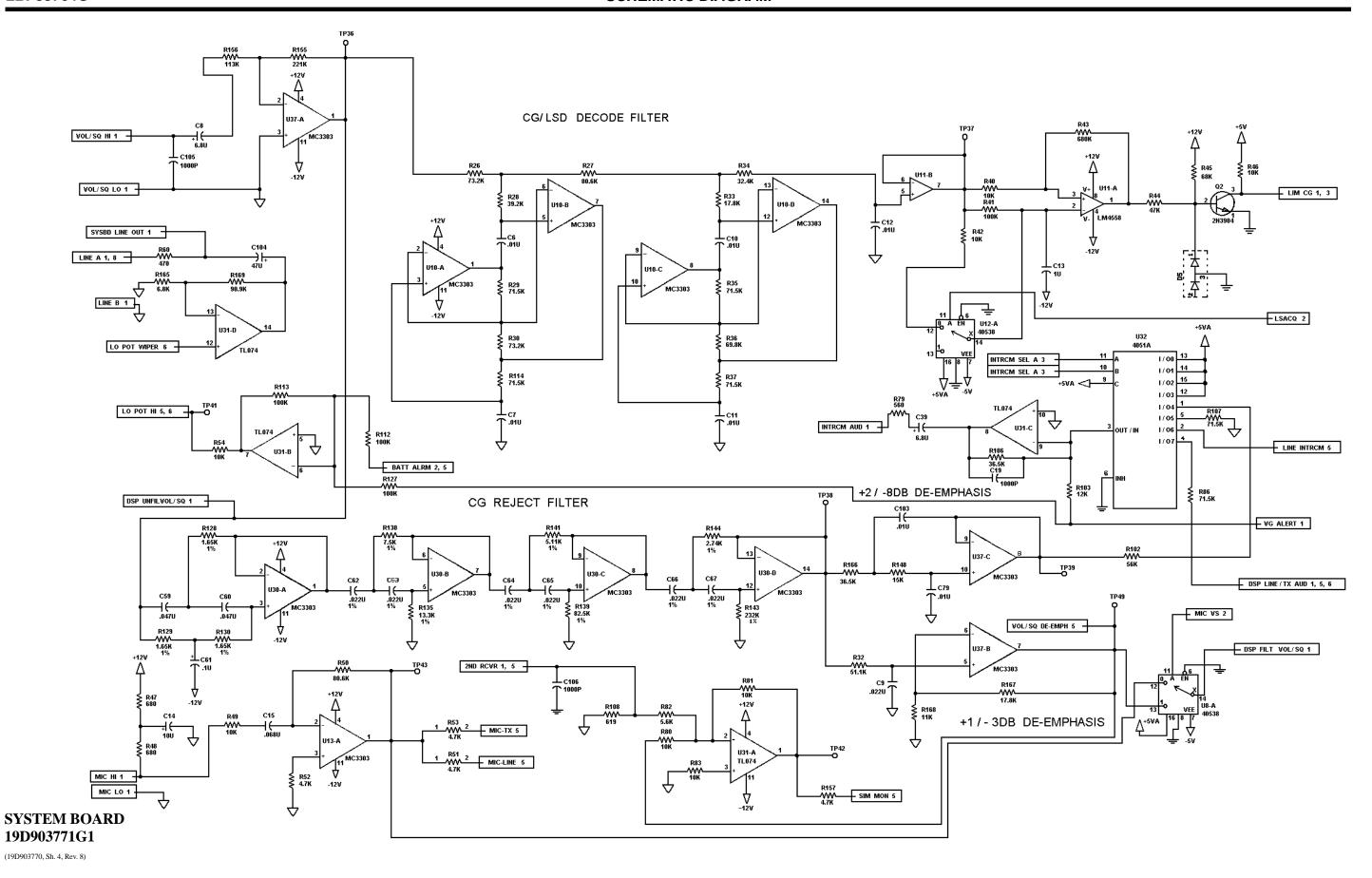


(19D903770, Sh. 2, Rev. 8)

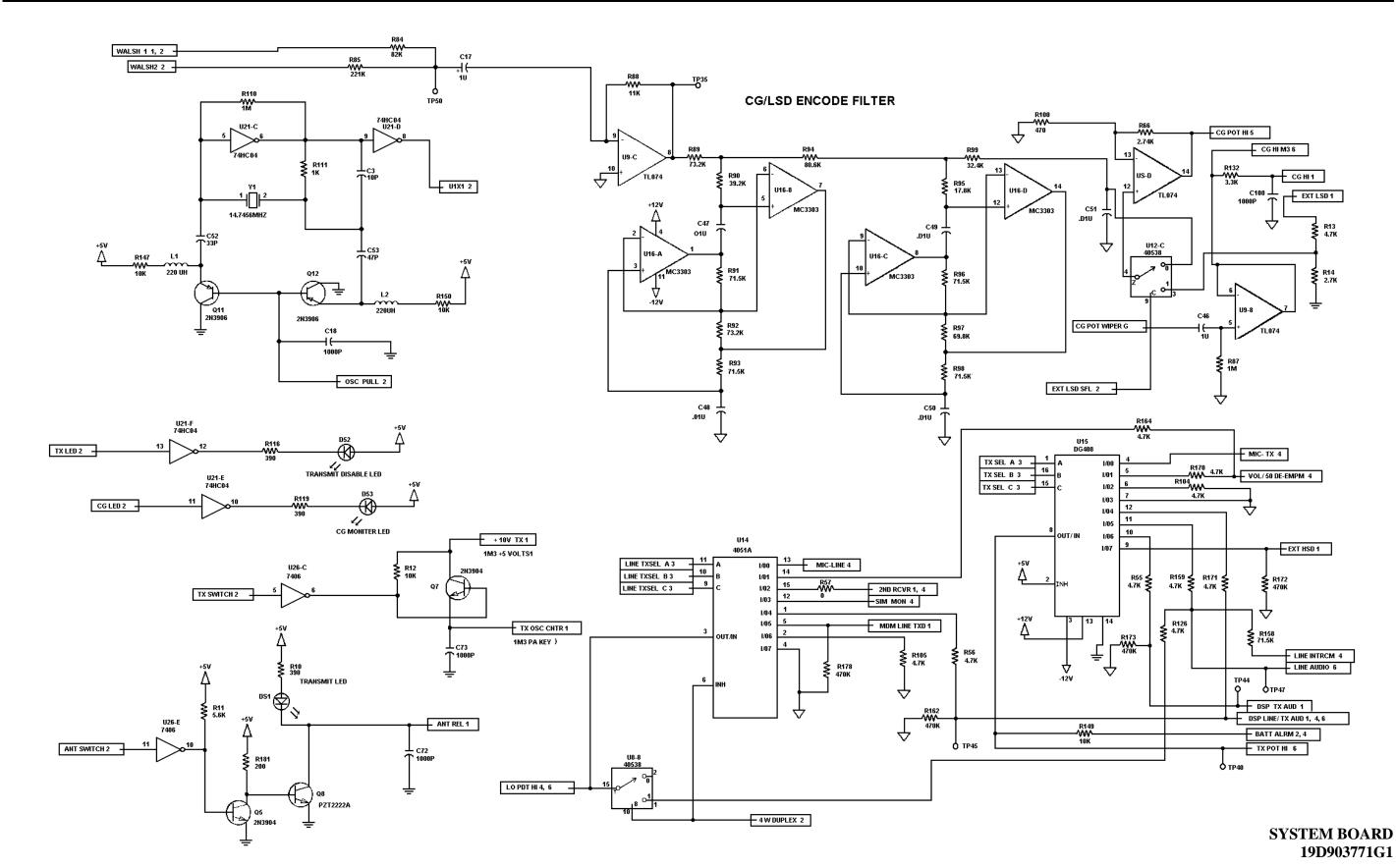


19D903771G1

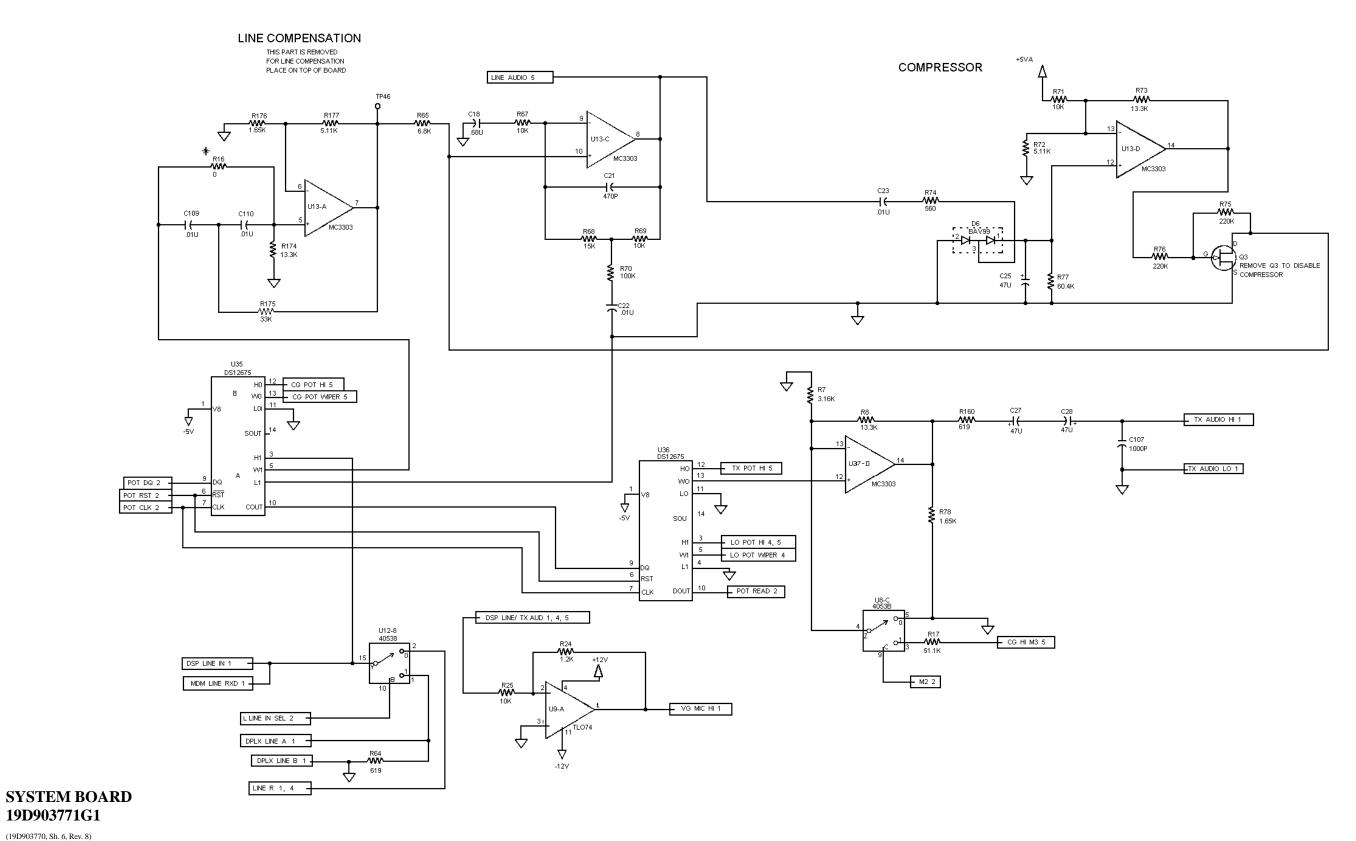
(19D903770, Sh. 3, Rev. 8)



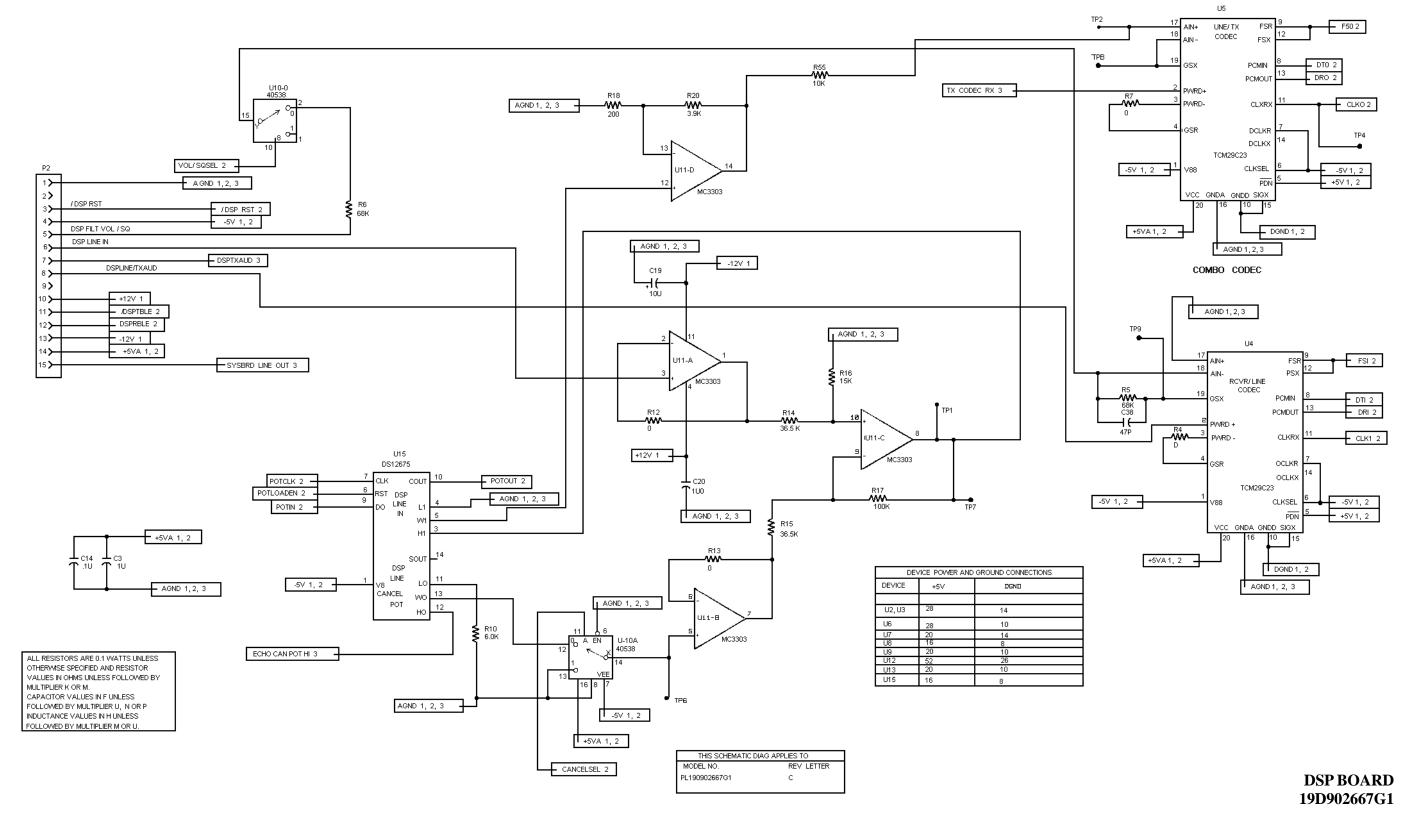
14



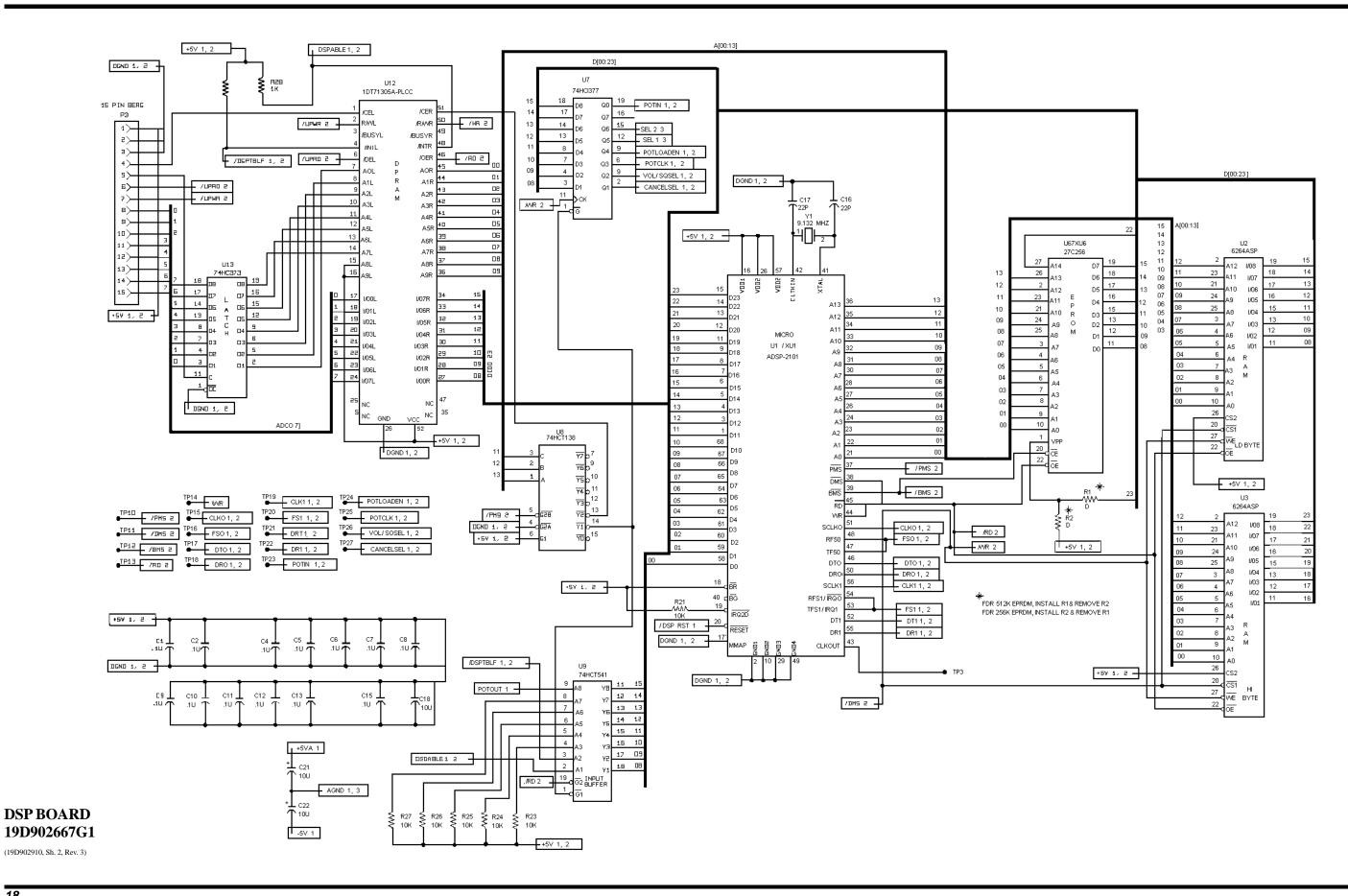
(19D903770, Sh. 5, Rev. 8)

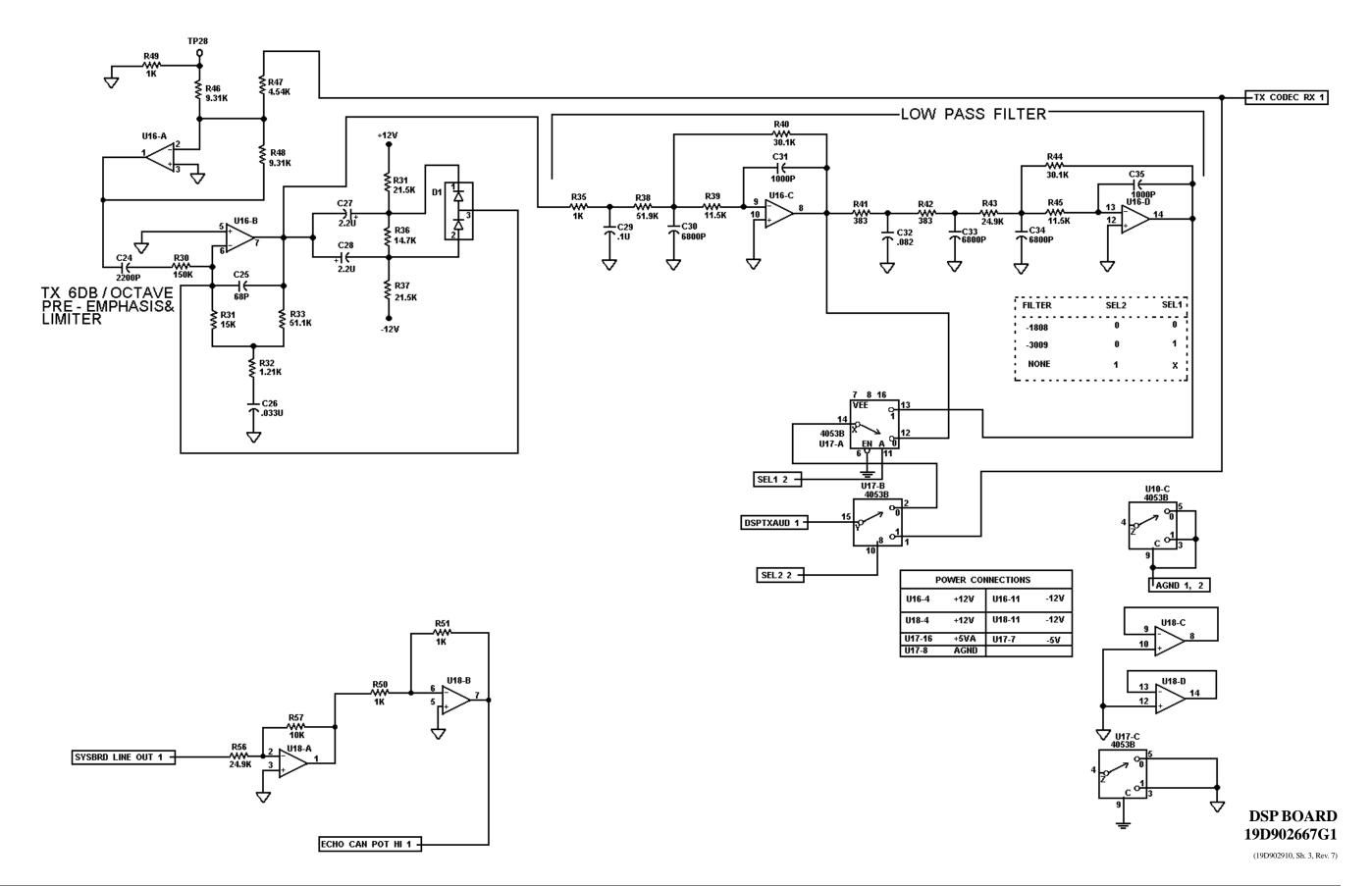


(19D903770, Sh. 6, Rev. 8)



(19D902910, Sh. 1, Rev. 9)

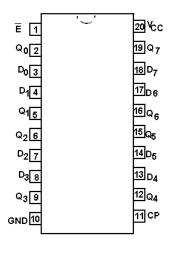




LBI-38764G IC DATA

EPROM Kit U4 8K x 8-Bit Static CMOS RAM U5 **SYSTEM MODULE** 344A3307G5 19A705603P5 (KM6264AL-10) Microcomputer, U1 19A705982P101 A15 1 28 Vcc TRUTH TABLE (INTEL 80C152JB-1) 27 A14 26 A13 A12∐ 2 VE CS CS OE MODE I/O PIN A7 🏻 3 × н × HIGH Z 25 🗌 A8 A6 ☐ 4 (POVER DOVN) HIGH Z A5 ☐ 5 24 🗖 A9 H L H H H L H L L H L OUTPUT DISABLED HIGH Z A4 ☐ 6 23 🗆 A11 DOUT READ BEN | 12 RESET | 13 P3.0 | 14 P3.1 | 15 P3.2 | 16 P5.0 | 17 P3.3 | 18 P3.4 | 19 P5.1 | 20 P5.2 | 21 P5.3 | 23 P5.8 | 24 L L L L H DIN **VRITE** PIN ARRANGEMENT 21 A10 D IN A1 🖥 9 20□ Ē 28 Vec 27 VE 26 CS2 25 A8 **BLOCK DIAGRAM** A0 ☐ 10 19 🗌 Q8 A12 2 Q1 🛮 11 18 🗖 Q7 80C152JB A73 Q2 🗌 12 17 🗖 Q6 X DECODER MEMORY CELL ARRAY Q3 🗌 13 16 🗌 Q5 A5 5 24 A9 GND ☐14 15 ☐ Q4 128 X 64 X 8 23 A11 22 OE 21 A10 A3 7 64 = 8 A2 8 COLUMN GATE A1 9 20 CS1 19 1/08 A0 10 1701 11 18 1/07 CS1 1/02 12 17 1/06 Octal Data Latch U2 1403 13 16 H05 BLOCK DIAGRAM 19A703471P302 (74HC373) ¥55 14 **I/O BUFFER** PIN ASSIGNMENT FUNCTION TABLE D0 -1/01 1/03 1/05 1/07 1/08 Output Enable Latch Enable Output Enable 1 Output 19 🛮 Q7 Q0 🛛 2 D0 🛚 3 18 D7 D1 🛚 4 × no change D5 14 Q1 🛚 5 16 DQ6 · Q5 X = don't care 15 🛮 Q5 Q2 🛮 6 Z = high impedance Optoisolator U6 D2 🛚 7 19A703952P102 13 D4 D3 🛮 8 (XICOR X2816CP-20) Q3 🗖 9 12 Q4 Latch Enable GND ☐ 10 Output Enable HIGH VOLTAGE Pin 20 = Vcc Pin 10 = GND A 5 6 A 4 7 A 3 8 A 2 9 A 1 1 10 A 0 11 NC 12 PUMP VOLTAGE POWER UP/DOWN WRITE PROJECT 3-to-8 Decoder/Demultiplexer U3 19A703471P120 (74HC138) WRITE NOISE PROJECT ADDRESS LATCHES PIN NAMES DATA LATCHES BUFFERS ADDRESS INPUTS DATA INPUTS/OUTPUTS I/O_O - I/O₇ CE OE WE CHIP ENABLE OUTPUT ENABLE WRITE ENABLE Vcc VxX NC +5V GROUND NO CONNECT

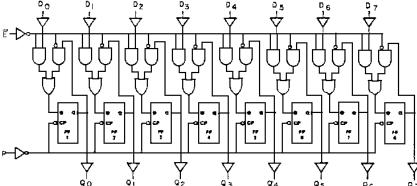
CMOS Octal Data Flip-Flop U7 19A704380P319 (74HC377)



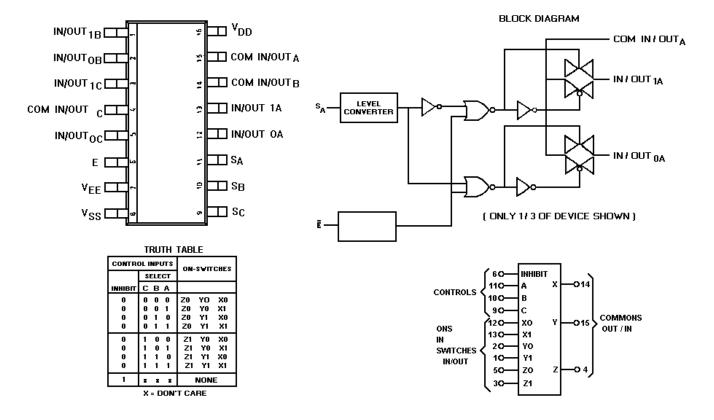
FUNCTION TABLE

OPERATING		INPUTS	5	OUTPUTS
MODES	СР	E	Dn	On
Load "1"	1	ı	h	Н
Load "O"	1	ı	1	L
Hold (do nothing)	† X	h H	X X	no change no change

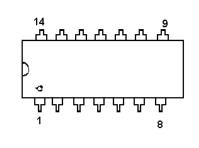
- H = HIGH voltage level
- h = HIGH voltage level one setup tone prior to the LOW-to-HIGH CP transition.
- L = LOW voltage level
- I = LOW voltage level one setup tone prio to the LOW-to-HIGH CP transition
- ↑ = LOW-to-HIGH CP transition

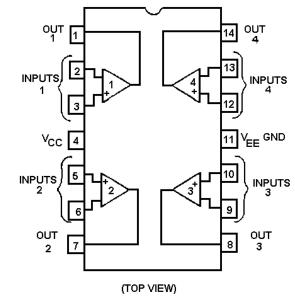


Triple 2-Channel Analog Multiplexer U8, U12 19A702705P5 (4053BM)

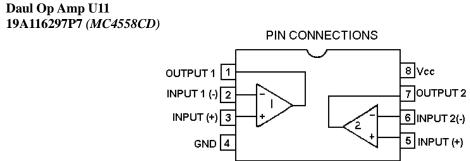


Operational Amplifier U9, U31 344A3070P3 (TL074) Operational Amplifier U10, U13, U16, U17, U30, & U37 19A704883P2 (MC3303D)

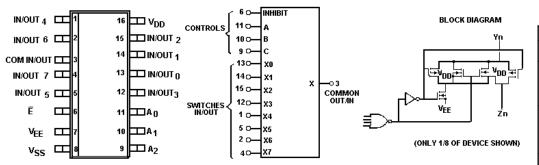




PIN CONNECTIONS



8-Channel Analog Multiplexer U14, U32, U33 19A702705P3 (4051BM)

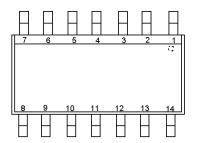


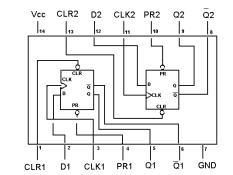
	CONTRO	L INPUTS	
	INHIBIT	SELECT	ON-SWITCHES
		СВА	1
	0	0 0 0	xo
₹Γ	0	001	X1
	0	010	X2
	0	011	Х3
	0	100	X4
	0	101	X5
	0	110	X6
M)	0	111	X7
	1	xxx	NONE
	X = DOI	I'T CARE	

SYSTEM MODULE

LBI-38764G IC DATA

CMOS Dual Data Flip-Flop U18, U28 19A704380P302 (74HC74)



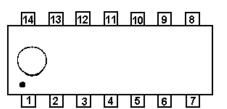


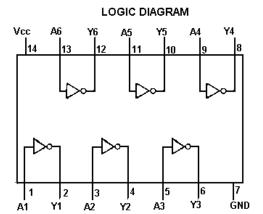
IN	NPUTS			OUTPU	TS
PR	CLR	CLK	D	Q	Q
L Н Н Н	H L H H	X X T T	X X H L X	H L H* H L Q0	L H H* L H_Q0

NOTE: Q0 = the level of Q before the indicated inout conditions were established. *This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.

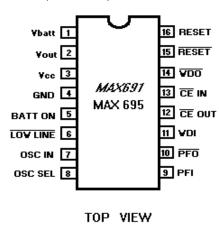
Hex Inverters U21 19A703995P3 (74HCU0-4)

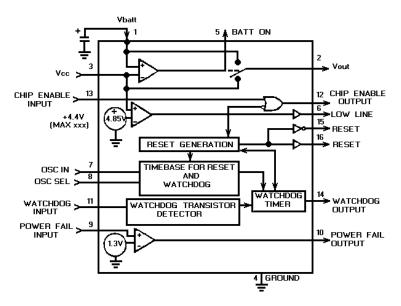
PIN CONFIGURATION



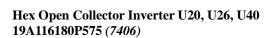


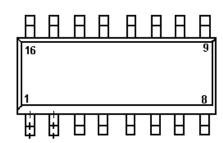
Supervisory Circuit U19





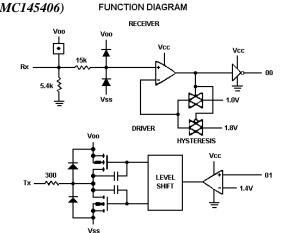
19A149895P1 (MAX691C)





SYSTEM MODULE

Driver/Receiver: EIA-232D/V.28 U22 344A3039P201 (MC145406)



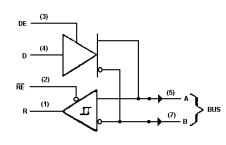
D = DRIVER R = RECEIVER

PIN ASSIGNMENT

Differential Bus Transceiver U24 19A705980P101 (SN751768)

RE 2 7 B DE 3 D 4

logic diagram (positive logic)



FUNCTION TABLE (DRIVER)

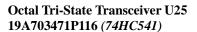
INPUT	ENABLE	OUTPUTS	
D	DE	Α	В
Н	Н	Н	L
L	Н	L	н
x	L	z	z

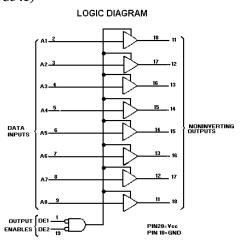
FUNCTION TABLE (RECEIVER)

DIFFERENTIAL INPUTS A - B	ENABLE RE	OUTPUT R
V _{ID} > 0.2V	L	Н
-0.2V < V _{ID} < 0.2V	L	?
V _{ID} < -0.2V	L	L
x	Н	Z

H = high level, L = low level, ? = indeter





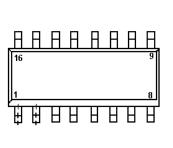


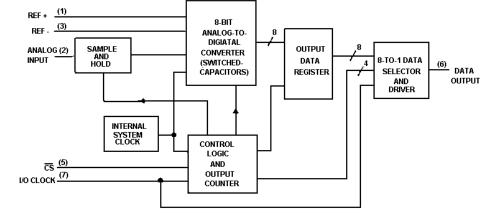
OE1 [1 #	20 Vcc
A1 [2	19 OE2
A2 🛘 3	18 Y1
A3 🛮 4	17 Y2
A4 🛭 5	16 Y3
A5 🗆 6	15 74
A6 🗆 7	14 Y5
A7 🗆 8	13 Y6
A8 🛮 9	12 Y7
GND II 10	11 D Y8

PIN ASSIGNMENT

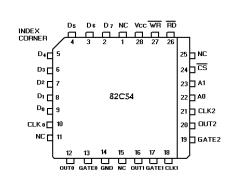
FUNCTION TABLE			
INPUTS		OUTPUTS	
OE1	OE2	Α	Y
L	L	L	L
L	L	н	н
н	×	×	z
×	н	x	z
Z= high impedance			

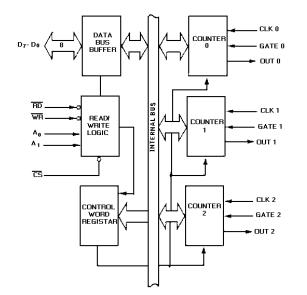
CMOS A/D Converter U27 19A705979P101 (*TL549CP*)



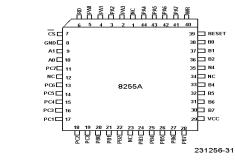


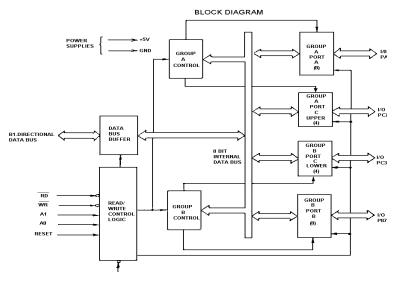
CH MOS Programmable Interval Timer U29 19A149466P301 (INTEL 82C54)



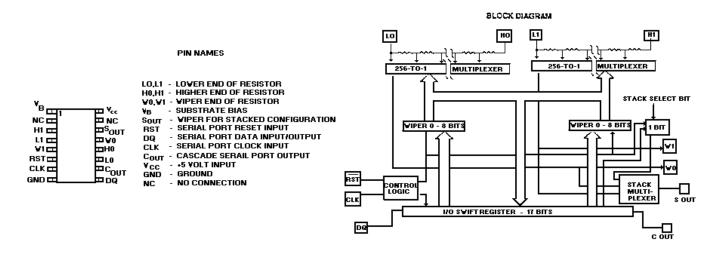


CH MOS Programmable Peripheral Interface U34 19A705991P101 (C82C55A)





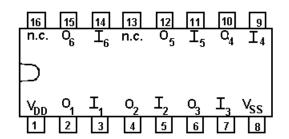
Digital Potentiometer U35, U36 344A3041P201 (DS1267S-10)



SYSTEM MODULE

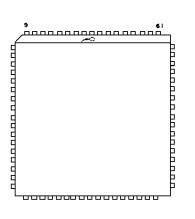
LBI-38764G IC DATA

Hex Inverting Buffer/Converter U41 19A700176P101 (4049UBD)

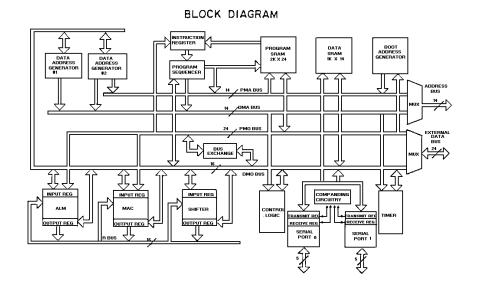


DSP BOARD

Digital Signal Processor U1 344A3038P101 (ADSP210KX-40)

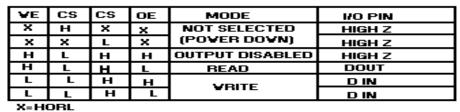


PIN NUMBER	PIN NAME	PIN NUMBER	PIN NAME
B1	GND	K11	WR
B2	D19	K10	RD
C1	D20	J11	DTO
C2	D21	J10	TFS0
D1	D22	H11	RFSQ
D2	D23	H10	GND
D1	Voo	G11	DRO
D2	MMAP	G10	SCLKO
F1	BR	F11	DT1
F2	1RQ2	F10	TFS1
G1	RESET	E11	RFS1
G2	AO	E10	DR1
H1	A1	D11	SCLK1
H2	A2	D10	VDD
J1	A3	C11	D0
J2	A4	C10	D1
К1	VDD	B11	D2
12	A5	A10	D3
K2	A6	B10	D4
L3	GND	A9	D5
кз	A7	B9	D6
L4	A8	A8	D7
K4	A9	B8	D8
L5	A10	A7	D9
К5	A11	B7	D10
L6	A12	A6	D11
K6	A13	B6	GND
1.7	PMS	A5	D12
K7	DMS	B5	D13
L8	BMS	A4	D14
К8	BG	B4	D15
L9	XTAL	A3	D16
К9	CLKIN	B3	D17
L10	CLKOUT	A2	D18
C3	Index		

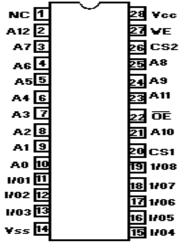


8K x 8-Bit Static CMOS RAM U2, U3 19A705603P5 (Deleted by Revision E)

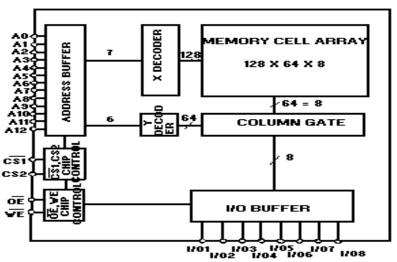
TRUTH TABLE



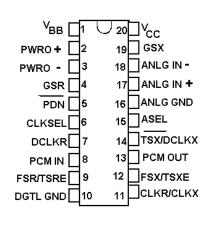
PIN ARRANGEMENT

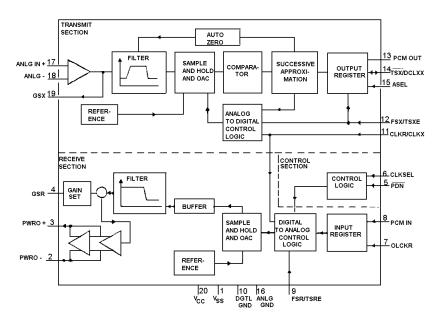


BLOCK DIAGRAM

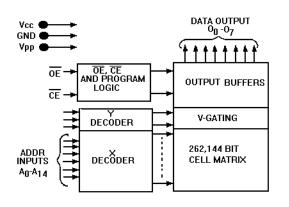


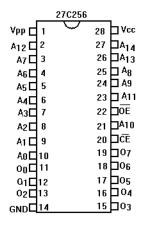
Encoder/Decoder U4, U5 19A705827P1 (*TCM29C23*)





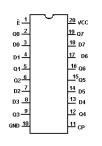
EPROM Kit U6 344A3309G5





PIN NAME		
ADDRESSES		
CHIP ENABLE		
OUTPUT ENABLE		
OUTPUTS		

CMOS Hi-Speed Octal D Type Flip-Flop With Data Enable U7 344A3064P203 (74HCT377)

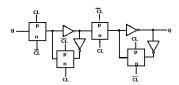


TRUTH TABLE

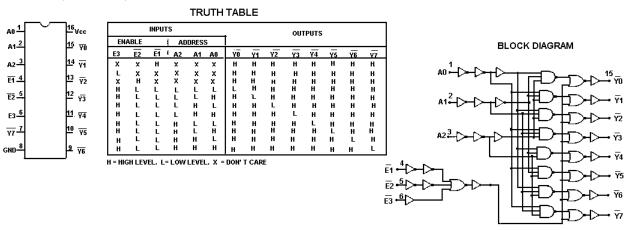
	INPUTS			OUTPUTS
OPERATING MODE	CP	Е	Dn	On
LOAD "1"	١,	1	h	Н
LOAD "0"	_	_	х	L
HOLD (do nothing)	<i>-</i>	h	х	no change no change

- = LOW to -HIGH clock

BLOCK DIAGRAM



CMOS Hi-Speed 3 To 8 Line Decoder/Demultiplexer U8 344A3064P201 (74HCT138)



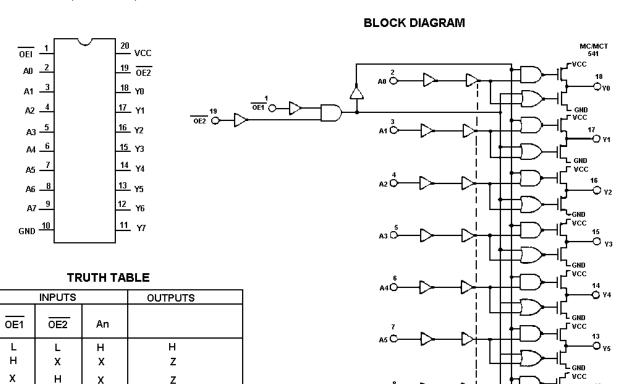
CMOS Hi-Speed Octal Buffer/Line Driver, 3 State U9 344A3064P204 (74HCT541)

Н

Х

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

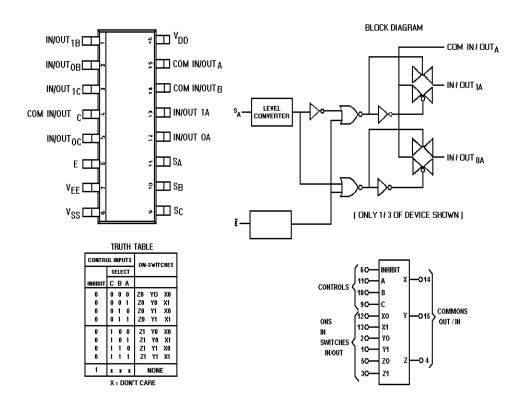
Ζ



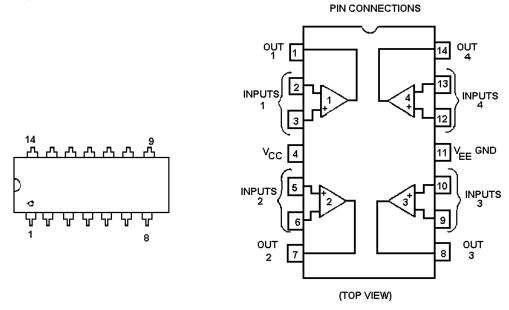
DSP BOARD

LBI-38764G IC DATA

Triple 2-Channel Analog Multiplexer U10 19A702705P5 (MC3303D)

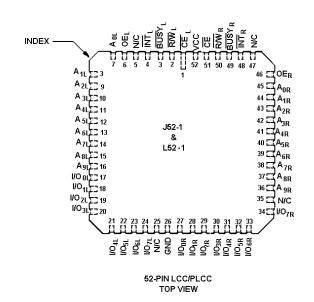


Quad Operational Amplifier U11 19A7048883P2 (MC4558CD)

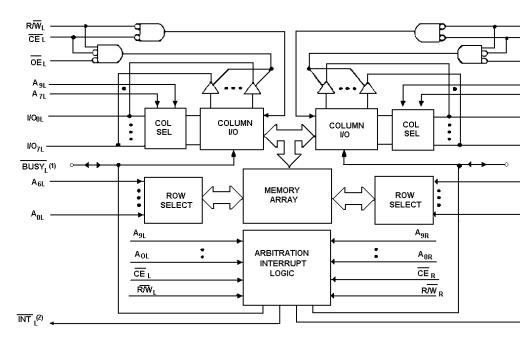


DSP BOARD

SRAM, 1K x 8, Dual Port U12 344A3040P201 (IDT7130SA100)



BLOCK DIAGRAM



NOTES:

- 1. IDT/130 (MASTER): BUSY IS OPEN DRAIN OUTPUT AND REQUIRES PULLUP RESISTOR. IDT7140(SLAVE): BUSY IS INPUT.
 2. OPEN DRAIN OUTPUT REQUIRES PULLUP RESISTOR.

CMOS Hi-Speed Octal Transparent Latch U13 344A3064P202 (74HCT373)

TRUTH TABLE

OUTPUT ENABLE	LATCH ENABLE	DATA	OUTPUT
L	н	н	н
L	н	L	L
L	L	ı	L
L	L	h	н
Н	<u>x</u>	х	Z
NOTE:			

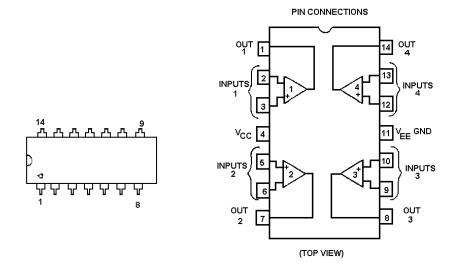
H = High voltage level Z = High impedance state
I = Low voltage level one set-up time prior to the high to
low latch enable transition
h = High voltage level one set-up time prior to the high

X = Don't care

h = High voltage level one set-up time prior to the high to low latch enable transition.

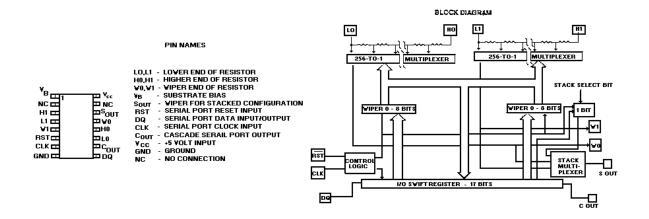
L = Low voltage level

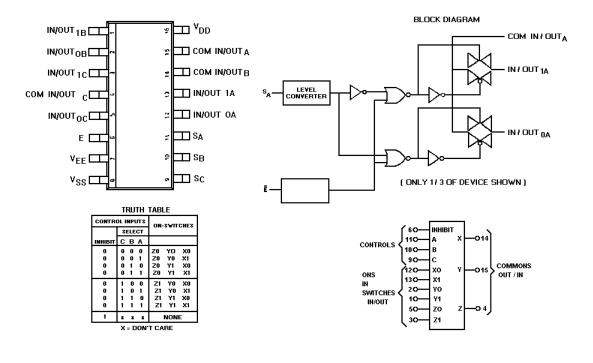
Operational Amplifier U16 344A3070P3 (*TL075*)



Triple 2-Channel Analog Multiplexer U17 19A702705P5 (4053BM)

Digital Potentiometer U15 344A3041P201 (DS1267S-10)





DSP BOARD